

# **MX25L4006E**

## **DATASHEET**

## Contents

|                                                                                |           |
|--------------------------------------------------------------------------------|-----------|
| <b>FEATURES .....</b>                                                          | <b>4</b>  |
| <b>GENERAL DESCRIPTION .....</b>                                               | <b>5</b>  |
| <b>PIN CONFIGURATIONS .....</b>                                                | <b>5</b>  |
| <b>PIN DESCRIPTION .....</b>                                                   | <b>5</b>  |
| <b>BLOCK DIAGRAM.....</b>                                                      | <b>6</b>  |
| <b>MEMORY ORGANIZATION .....</b>                                               | <b>7</b>  |
| Table 1. Memory Organization .....                                             | 7         |
| <b>DEVICE OPERATION .....</b>                                                  | <b>8</b>  |
| Figure 1. Serial Peripheral Interface Modes Supported .....                    | 8         |
| <b>DATA PROTECTION.....</b>                                                    | <b>9</b>  |
| Table 2. Protected Area Sizes .....                                            | 9         |
| <b>HOLD FEATURE.....</b>                                                       | <b>10</b> |
| Figure 2. Hold Condition Operation .....                                       | 10        |
| Table 3. COMMAND DEFINITION .....                                              | 11        |
| <b>COMMAND DESCRIPTION.....</b>                                                | <b>12</b> |
| (1) Write Enable (WREN) .....                                                  | 12        |
| (2) Write Disable (WRDI).....                                                  | 12        |
| (3) Read Status Register (RDSR) .....                                          | 13        |
| (4) Write Status Register (WRSR).....                                          | 14        |
| Table 4. Protection Modes.....                                                 | 14        |
| (5) Read Data Bytes (READ) .....                                               | 15        |
| (6) Read Data Bytes at Higher Speed (FAST_READ) .....                          | 15        |
| (7) Dual Output Mode (DREAD).....                                              | 15        |
| (8) Sector Erase (SE) .....                                                    | 15        |
| (9) Block Erase (BE).....                                                      | 16        |
| (10) Chip Erase (CE).....                                                      | 16        |
| (11) Page Program (PP).....                                                    | 16        |
| (12) Deep Power-down (DP) .....                                                | 17        |
| (13) Release from Deep Power-down (RDP), Read Electronic Signature (RES) ..... | 17        |
| (14) Read Identification (RDID) .....                                          | 18        |
| (15) Read Electronic Manufacturer ID & Device ID (REMS).....                   | 18        |
| Table 5. ID Definitions .....                                                  | 18        |
| (16) Read SFDP Mode (RDSFDP).....                                              | 19        |
| Read Serial Flash Discoverable Parameter (RDSFDP) Sequence.....                | 19        |
| Table a. Signature and Parameter Identification Data Values .....              | 20        |
| Table b. Parameter Table (0): JEDEC Flash Parameter Tables .....               | 21        |
| Table c. Parameter Table (1): Macronix Flash Parameter Tables.....             | 23        |
| <b>POWER-ON STATE .....</b>                                                    | <b>25</b> |
| <b>ELECTRICAL SPECIFICATIONS.....</b>                                          | <b>26</b> |
| ABSOLUTE MAXIMUM RATINGS .....                                                 | 26        |

|                                                                                       |           |
|---------------------------------------------------------------------------------------|-----------|
| Figure 3. Maximum Negative Overshoot Waveform .....                                   | 26        |
| CAPACITANCE TA = 25°C, f = 1.0 MHz.....                                               | 26        |
| Figure 4. Maximum Positive Overshoot Waveform .....                                   | 26        |
| Figure 5. INPUT TEST WAVEFORMS AND MEASUREMENT LEVEL.....                             | 27        |
| Figure 6. OUTPUT LOADING .....                                                        | 27        |
| Table 6. DC CHARACTERISTICS (Temperature = -40°C to 85°C, VCC = 2.7V ~ 3.6V) .....    | 28        |
| Table 7. AC CHARACTERISTICS (Temperature = -40°C to 85°C, VCC = 2.7V ~ 3.6V) .....    | 29        |
| Table 8. Power-Up Timing .....                                                        | 30        |
| <b>Timing Analysis .....</b>                                                          | <b>31</b> |
| Figure 7. Serial Input Timing .....                                                   | 31        |
| Figure 8. Output Timing.....                                                          | 31        |
| Figure 9. Hold Timing .....                                                           | 32        |
| Figure 10. WP# Disable Setup and Hold Timing during WRSR when SRWD=1 .....            | 32        |
| Figure 11. Write Enable (WREN) Sequence (Command 06) .....                            | 33        |
| Figure 12. Write Disable (WRDI) Sequence (Command 04).....                            | 33        |
| Figure 13. Read Status Register (RDSR) Sequence (Command 05) .....                    | 33        |
| Figure 14. Write Status Register (WRSR) Sequence (Command 01).....                    | 34        |
| Figure 15. Read Data Bytes (READ) Sequence (Command 03) .....                         | 34        |
| Figure 16. Read at Higher Speed (FAST_READ) Sequence (Command 0B).....                | 35        |
| Figure 17. Dual Output Read Mode Sequence (Command 3B).....                           | 35        |
| Figure 18. Sector Erase (SE) Sequence (Command 20).....                               | 36        |
| Figure 19. Block Erase (BE) Sequence (Command 52 or D8).....                          | 36        |
| Figure 20. Chip Erase (CE) Sequence (Command 60 or C7).....                           | 36        |
| Figure 21. Page Program (PP) Sequence (Command 02).....                               | 37        |
| Figure 22. Deep Power-down (DP) Sequence (Command B9).....                            | 37        |
| Figure 23. Read Electronic Signature (RES) Sequence (Command AB).....                 | 38        |
| Figure 24. Release from Deep Power-down (RDP) Sequence (Command AB) .....             | 38        |
| Figure 25. Read Identification (RDID) Sequence (Command 9F).....                      | 39        |
| Figure 26. Read Electronic Manufacturer & Device ID (REMS) Sequence (Command 90)..... | 39        |
| Figure 27. Power-up Timing .....                                                      | 40        |
| <b>OPERATING CONDITIONS .....</b>                                                     | <b>41</b> |
| Figure 28. AC Timing at Device Power-Up.....                                          | 41        |
| Figure 29. Power-Down Sequence .....                                                  | 42        |
| <b>ERASE AND PROGRAMMING PERFORMANCE .....</b>                                        | <b>43</b> |
| <b>DATA RETENTION .....</b>                                                           | <b>43</b> |
| <b>LATCH-UP CHARACTERISTICS .....</b>                                                 | <b>43</b> |
| <b>ORDERING INFORMATION .....</b>                                                     | <b>44</b> |
| <b>PART NAME DESCRIPTION .....</b>                                                    | <b>45</b> |
| <b>PACKAGE INFORMATION.....</b>                                                       | <b>46</b> |
| <b>REVISION HISTORY .....</b>                                                         | <b>51</b> |

**4M-BIT [x 1/x 2] CMOS SERIAL FLASH****FEATURES****GENERAL**

- Serial Peripheral Interface compatible -- Mode 0 and Mode 3
- 4,194,304 x 1 bit structure or 2,097,152 x 2 bits (Dual Output mode) structure
- 128 Equal Sectors with 4K byte each
  - Any Sector can be erased individually
- 8 Equal Blocks with 64K byte each
  - Any Block can be erased individually
- Single Power Supply Operation
  - 2.7 to 3.6 volt for read, erase, and program operations
- Latch-up protected to 100mA from -1V to Vcc +1V

**PERFORMANCE**

- High Performance
  - Fast access time: 86MHz serial clock
  - Serial clock of Dual Output mode: 80MHz
  - Fast program time: 1.4ms(typ.) and 5ms(max.)/page (256-byte per page)
  - Byte program time: 9us
  - Fast erase time: 60ms(typ.)/sector (4K-byte per sector) ; 0.7s(typ.)/block (64K-byte per block)
- Low Power Consumption
  - Low active read current: 12mA(max.) at 86MHz and 4mA(max.) at 33MHz
  - Low active programming current: 20mA (max.)
  - Low active erase current: 20mA (max.)
  - Low standby current: 25uA (max.)
  - Deep power-down mode 5uA (typ.)
- Minimum 100,000 erase/program cycles
- 20 years data retention

**SOFTWARE FEATURES**

- Input Data Format
  - 1-byte Command code
- Block Lock protection
  - The BP0~BP2 status bit defines the size of the area to be software protected against Program and Erase instructions
- Auto Erase and Auto Program Algorithm
  - Automatically erases and verifies data at selected sector
  - Automatically programs and verifies data at selected page by an internal algorithm that automatically times the program pulse widths (Any page to be programmed should have page in the erased state first)
- Status Register Feature
- Electronic Identification
  - JEDEC 2-byte Device ID
  - RES command, 1-byte Device ID
- Support Serial Flash Discoverable Parameters (SFDP) mode

**HARDWARE FEATURES**

- PACKAGE
  - 8-pin SOP (150mil)
  - 8-pin SOP (200mil)
  - 8-pin PDIP (300mil)
  - 8-land WSON (6x5mm, 0.8mm package height)
  - 8-land USON (2x3x0.6mm)
  - **All devices are RoHS Compliant**

## GENERAL DESCRIPTION

The device features a serial peripheral interface and software protocol allowing operation on a simple 3-wire bus. The four bus signals are a clock input (SCLK), a serial data input (SI), a serial data output (SO), and a chip select (CS#). Serial access to the device is enabled by CS# input.

When it is in Dual Output read mode, the SI and SO pins become SIO0 and SIO1 pins for data output.

The device provides sequential read operation on whole chip.

After program/erase command is issued, auto program/erase algorithms which program/erase and verify the specified page or sector/block locations will be executed. Program command is executed on byte basis, or page basis, or word basis for erase command is executes on sector, or block, or whole chip basis.

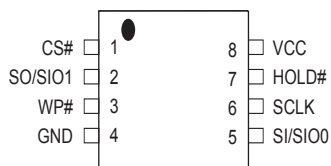
To provide user with ease of interface, a status register is included to indicate the status of the chip. The status read command can be issued to detect completion status of a program or erase operation via WIP bit.

When the device is not in operation and CS# is high, it is put in standby mode.

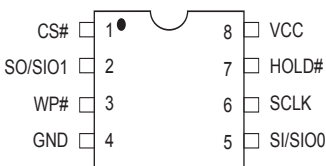
The device utilizes Macronix's proprietary memory cell, which reliably stores memory contents even after 100,000 program and erase cycles.

## PIN CONFIGURATIONS

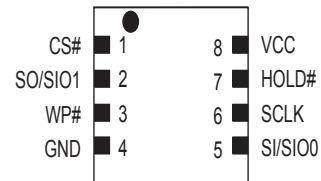
### 8-PIN SOP (150/200mil)



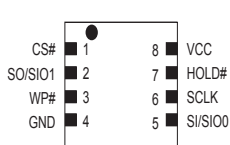
### 8-PIN PDIP (300mil)



### 8-LAND, WSON (6x5mm)

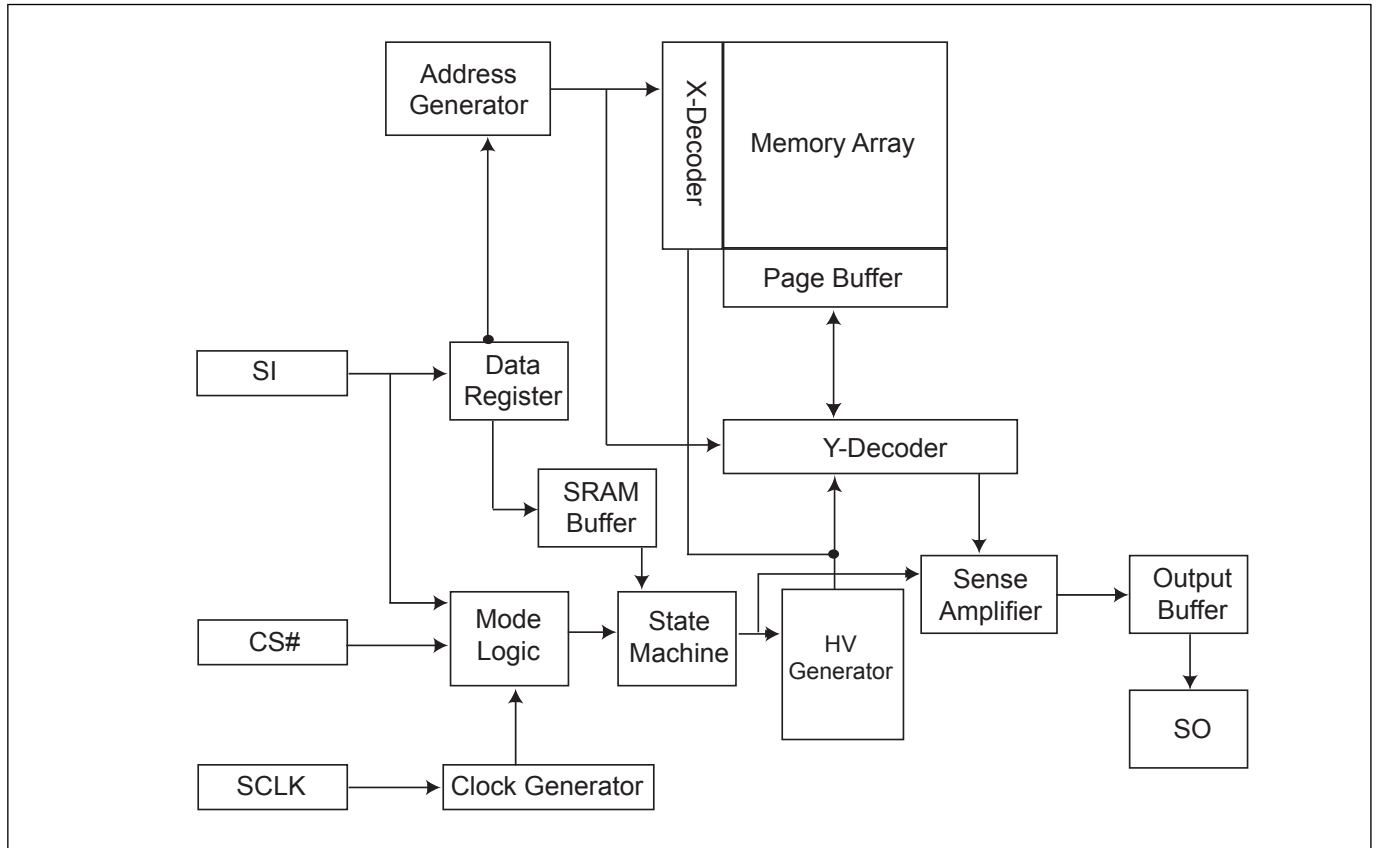


### 8-LAND USON (2x3mm)



## PIN DESCRIPTION

| SYMBOL  | DESCRIPTION                                                                         |
|---------|-------------------------------------------------------------------------------------|
| CS#     | Chip Select                                                                         |
| SI/SIO0 | Serial Data Input (for 1 x I/O) / Serial Data Input & Output (for Dual Output mode) |
| SO/SIO1 | Serial Data Output (for 1 x I/O) / Serial Data Output (for Dual Output mode)        |
| SCLK    | Clock Input                                                                         |
| WP#     | Write Protection                                                                    |
| HOLD#   | Hold, to pause the device without deselecting the device                            |
| VCC     | + 3.3V Power Supply                                                                 |
| GND     | Ground                                                                              |

**BLOCK DIAGRAM**

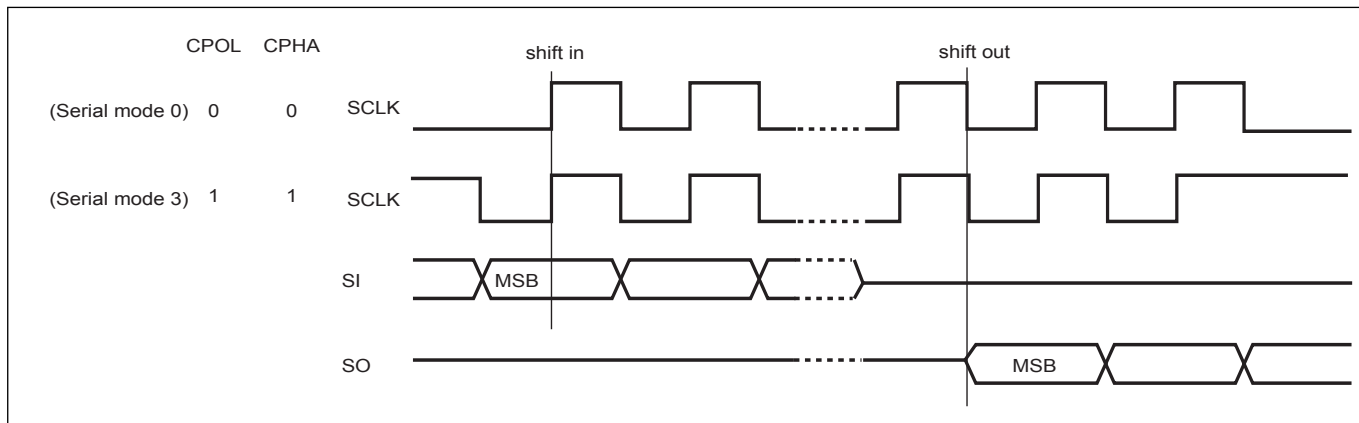
**MEMORY ORGANIZATION****Table 1. Memory Organization**

| Block | Sector | Address Range |         |
|-------|--------|---------------|---------|
| 7     | 127    | 07F000h       | 07FFFFh |
|       | :      | :             | :       |
|       | 112    | 070000h       | 070FFFh |
| 6     | 111    | 06F000h       | 06FFFFh |
|       | :      | :             | :       |
|       | 96     | 060000h       | 060FFFh |
| 5     | 95     | 05F000h       | 05FFFFh |
|       | :      | :             | :       |
|       | 80     | 050000h       | 050FFFh |
| 4     | 79     | 04F000h       | 04FFFFh |
|       | :      | :             | :       |
|       | 64     | 040000h       | 040FFFh |
| 3     | 63     | 03F000h       | 03FFFFh |
|       | :      | :             | :       |
|       | 48     | 030000h       | 030FFFh |
| 2     | 47     | 02F000h       | 02FFFFh |
|       | :      | :             | :       |
|       | 32     | 020000h       | 020FFFh |
| 1     | 31     | 01F000h       | 01FFFFh |
|       | :      | :             | :       |
|       | 16     | 010000h       | 010FFFh |
| 0     | 15     | 00F000h       | 00FFFFh |
|       | :      | :             | :       |
|       | 3      | 003000h       | 003FFFh |
|       | 2      | 002000h       | 002FFFh |
|       | 1      | 001000h       | 001FFFh |
|       | 0      | 000000h       | 000FFFh |

## DEVICE OPERATION

1. Before a command is issued, status register should be checked to ensure device is ready for the intended operation.
2. When incorrect command is inputted to this LSI, this LSI becomes standby mode and keeps the standby mode until next CS# falling edge. In standby mode, SO pin of this LSI should be High-Z. The CS# falling time needs to follow tCHCL spec.
3. When correct command is inputted to this LSI, this LSI becomes active mode and keeps the active mode until next CS# rising edge. The CS# rising time needs to follow tCLCH spec.
4. Input data is latched on the rising edge of Serial Clock(SCLK) and data shifts out on the falling edge of SCLK. The difference of serial peripheral interface mode 0 and mode 3 is shown as Figure 1.
5. For the following instructions: RDID, RDSR, READ, FAST\_READ, RDSFDP, DREAD, RES and REMS the shift-in instruction sequence is followed by a data-out sequence. After any bit of data being shifted out, the CS# can be high. For the following instructions: WREN, WRDI, WRSR, SE, BE, CE, PP, RDP and DP the CS# must go high exactly at the byte boundary; otherwise, the instruction will be rejected and not executed.
6. During the progress of Write Status Register, Program, Erase operation, to access the memory array is neglected and not affect the current operation of Write Status Register, Program, Erase.

**Figure 1. Serial Peripheral Interface Modes Supported**



**Note:**

CPOL indicates clock polarity of serial master, CPOL=1 for SCLK high while idle, CPOL=0 for SCLK low while not transmitting. CPHA indicates clock phase. The combination of CPOL bit and CPHA bit decides which serial mode is supported.



**DATA PROTECTION**

The device is designed to offer protection against accidental erasure or programming caused by spurious system level signals that may exist during power transition. During power up the device automatically resets the state machine in the standby mode. In addition, with its control register architecture, alteration of the memory contents only occurs after successful completion of specific command sequences. The device also incorporates several features to prevent inadvertent write cycles resulting from VCC power-up and power-down transition or system noise.

- Valid command length checking: The command length will be checked whether it is at byte base and completed on byte boundary.
- Write Enable (WREN) command: WREN command is required to set the Write Enable Latch bit (WEL) before other command to change data. The WEL bit will return to reset stage under following situation:
  - Power-up
  - Write Disable (WRDI) command completion
  - Write Status Register (WRSR) command completion
  - Page Program (PP) command completion
  - Sector Erase (SE) command completion
  - Block Erase (BE) command completion
  - Chip Erase (CE) command completion
- Deep Power Down Mode: By entering deep power down mode, the flash device also is under protected from writing all commands except Release from deep power down mode command (RDP) and Read Electronic Signature command (RES).

**I. Block lock protection**

- Software Protection Mode (SPM): by using BP0-BP2 bits to set the part of Flash protected from data change.
- Hardware Protection Mode (HPM): by using WP# going low to protect the BP0-BP2 bits and SRWD bit from data change.

**Table 2. Protected Area Sizes**

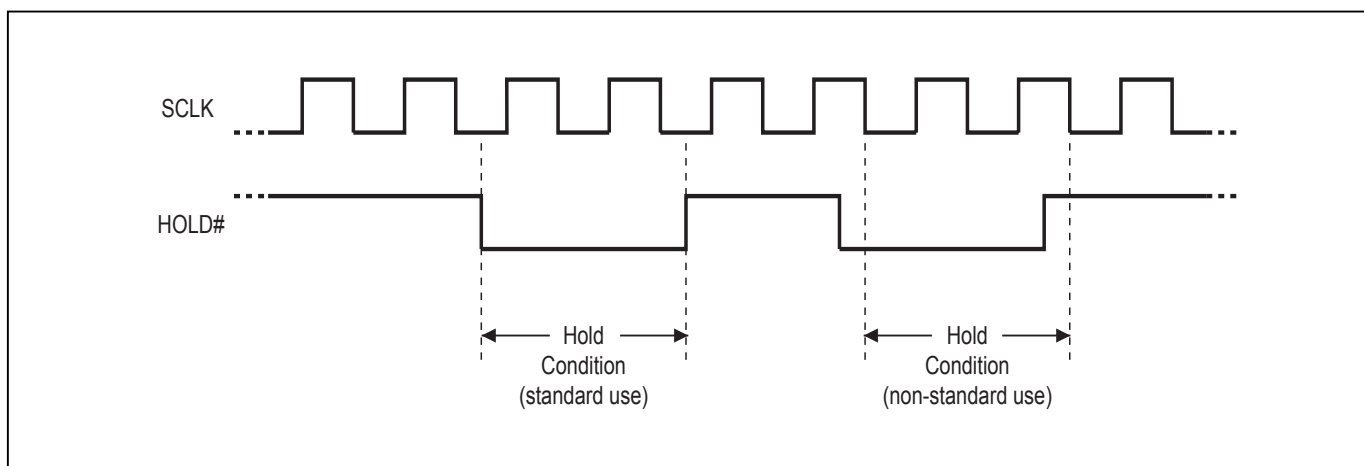
| Status bit |     |     | Protect level | 4Mb       |
|------------|-----|-----|---------------|-----------|
| BP2        | BP1 | BP0 |               |           |
| 0          | 0   | 0   | 0 (none)      | None      |
| 0          | 0   | 1   | 1 (1 block)   | Block 7   |
| 0          | 1   | 0   | 2 (2 blocks)  | Block 6-7 |
| 0          | 1   | 1   | 3 (4 blocks)  | Block 4-7 |
| 1          | 0   | 0   | 4 (8 blocks)  | All       |
| 1          | 0   | 1   | 5 (All)       | All       |
| 1          | 1   | 0   | 6 (All)       | All       |
| 1          | 1   | 1   | 7 (All)       | All       |

## HOLD FEATURE

HOLD# pin signal goes low to hold any serial communications with the device. The HOLD feature will not stop the operation of write status register, programming, or erasing in progress.

The operation of HOLD requires Chip Select(CS#) keeping low and starts on falling edge of HOLD# pin signal while Serial Clock (SCLK) signal is being low (if Serial Clock signal is not being low, HOLD operation will not start until Serial Clock signal being low). The HOLD condition ends on the rising edge of HOLD# pin signal while Serial Clock(SCLK) signal is being low (if Serial Clock signal is not being low, HOLD operation will not end until Serial Clock being low), see Figure 2.

**Figure 2. Hold Condition Operation**



The Serial Data Output (SO) is high impedance, both Serial Data Input (SI) and Serial Clock (SCLK) are don't care during the HOLD operation. If Chip Select (CS#) drives high during HOLD operation, it will reset the internal logic of the device. To re-start communication with chip, the HOLD# must be at high and CS# must be at low.

**Table 3. COMMAND DEFINITION**

| COMMAND (byte) | WREN (write Enable)                   | WRDI (write disable)                   | WRSR (write status register) | RDID (read identification)                      | RDSR (read status register)     | READ (read data)                     | Fast Read (fast read data)           |
|----------------|---------------------------------------|----------------------------------------|------------------------------|-------------------------------------------------|---------------------------------|--------------------------------------|--------------------------------------|
| 1st            | 06 Hex                                | 04 Hex                                 | 01 Hex                       | 9F Hex                                          | 05 Hex                          | 03 Hex                               | 0B Hex                               |
| 2nd            |                                       |                                        |                              |                                                 |                                 | AD1                                  | AD1                                  |
| 3rd            |                                       |                                        |                              |                                                 |                                 | AD2                                  | AD2                                  |
| 4th            |                                       |                                        |                              |                                                 |                                 | AD3                                  | AD3                                  |
| 5th            |                                       |                                        |                              |                                                 |                                 |                                      | Dummy                                |
| Action         | sets the (WEL) write enable latch bit | reset the (WEL) write enable latch bit | to write new status register | output the manufacturer ID and 2-byte device ID | to read out the status register | n bytes read out until CS# goes high | n bytes read out until CS# goes high |

| COMMAND (byte) | RDSFDP (Read SFDP) | RES (Read Electronic ID)     | REMS (Read Electronic Manufacturer & Device ID) | DREAD (Double Output Mode command)                  | SE (Sector Erase)            | BE (Block Erase)            | CE (Chip Erase)     |
|----------------|--------------------|------------------------------|-------------------------------------------------|-----------------------------------------------------|------------------------------|-----------------------------|---------------------|
| 1st            | 5A Hex             | AB Hex                       | 90 Hex                                          | 3B Hex                                              | 20 Hex                       | 52 or D8 Hex                | 60 or C7 Hex        |
| 2nd            | AD1                | x                            | x                                               | AD1                                                 | AD1                          | AD1                         |                     |
| 3rd            | AD2                | x                            | x                                               | AD2                                                 | AD2                          | AD2                         |                     |
| 4th            | AD3                | x                            | ADD(1)                                          | AD3                                                 | AD3                          | AD3                         |                     |
| 5th            | Dummy              |                              |                                                 | Dummy                                               |                              |                             |                     |
| Action         | Read SFDP mode     | to read out 1-byte Device ID | Output the manufacturer ID and device ID        | n bytes read out by Dual Output until CS# goes high | to erase the selected sector | to erase the selected block | to erase whole chip |

| COMMAND (byte) | PP (Page Program)            | DP (Deep Power Down)        | RDP (Release from Deep Power-down) |
|----------------|------------------------------|-----------------------------|------------------------------------|
| 1st            | 02 Hex                       | B9 Hex                      | AB Hex                             |
| 2nd            | AD1                          |                             |                                    |
| 3rd            | AD2                          |                             |                                    |
| 4th            | AD3                          |                             |                                    |
| 5th            |                              |                             |                                    |
| Action         | to program the selected page | enters deep power down mode | release from deep power down mode  |

(1) ADD=00H will output the manufacturer's ID first and ADD=01H will output device ID first.

(2) It is not recommended to adopt any other code which is not in the above command definition table.

**COMMAND DESCRIPTION****(1) Write Enable (WREN)**

The Write Enable (WREN) instruction is for setting Write Enable Latch (WEL) bit. For those instructions like PP, SE, BE, CE, and WRSR, which are intended to change the device content, should be set every time after the WREN instruction setting the WEL bit.

The sequence is shown as [Figure 11](#).

**(2) Write Disable (WRDI)**

The Write Disable (WRDI) instruction is for resetting Write Enable Latch (WEL) bit.

The sequence is shown as [Figure 12](#).

The WEL bit is reset by following situations:

- Power-up
- Write Disable (WRDI) instruction completion
- Write Status Register (WRSR) instruction completion
- Page Program (PP) instruction completion
- Sector Erase (SE) instruction completion
- Block Erase (BE) instruction completion
- Chip Erase (CE) instruction completion

## (3) Read Status Register (RDSR)

The RDSR instruction is for reading Status Register Bits. The Read Status Register can be read at any time (even in program/erase/write status register condition) and continuously. It is recommended to check the Write in Progress (WIP) bit before sending a new instruction when a program, erase, or write status register operation is in progress.

The sequence is shown as [Figure 13](#).

The definition of the status register bits is as below:

**WIP bit.** The Write in Progress (WIP) bit, a volatile bit, indicates whether the device is busy in program/erase/write status register progress. When WIP bit sets to 1, which means the device is busy in program/erase/write status register progress. When WIP bit sets to 0, which means the device is not in progress of program/erase/write status register cycle.

**WEL bit.** The Write Enable Latch (WEL) bit, a volatile bit, indicates whether the device is set to internal write enable latch. When WEL bit sets to 1, which means the internal write enable latch is set, the device can accept program/erase/write status register instruction. When WEL bit sets to 0, which means no internal write enable latch; the device will not accept program/erase/write status register instruction.

**BP2, BP1, BP0 bits.** The Block Protect (BP2, BP1, BP0) bits, non-volatile bits, indicate the protected area(as defined in table 2) of the device to against the program/erase instruction without hardware protection mode being set. To write the Block Protect (BP2, BP1, BP0) bits requires the Write Status Register (WRSR) instruction to be executed. Those bits define the protected area of the memory to against Page Program (PP), Sector Erase (SE), Block Erase (BE) and Chip Erase(CE) instructions (only if all Block Protect bits set to 0, the CE instruction can be executed)

**SRWD bit.** The Status Register Write Disable (SRWD) bit, non-volatile bit, is operated together with Write Protection (WP#) pin for providing hardware protection mode. The hardware protection mode requires SRWD sets to 1 and WP# pin signal is low stage. In the hardware protection mode, the Write Status Register (WRSR) instruction is no longer accepted for execution and the SRWD bit and Block Protect bits (BP2, BP1, BP0) are read only.

| bit 7                              | bit 6 | bit 5 | bit 4                                 | bit 3                                 | bit 2                                 | bit 1                                | bit 0                                         |
|------------------------------------|-------|-------|---------------------------------------|---------------------------------------|---------------------------------------|--------------------------------------|-----------------------------------------------|
| SRWD Status Register Write Protect | 0     | 0     | BP2<br>(the level of protected block) | BP1<br>(the level of protected block) | BP0<br>(the level of protected block) | WEL (write enable latch)             | WIP (write in progress bit)                   |
| 1= status register write disable   | 0     | 0     | (note 1)                              | (note 1)                              | (note 1)                              | 1=write enable<br>0=not write enable | 1=write operation<br>0=not in write operation |

**Note:**

1. See the table "Protected Area Sizes".

#### (4) Write Status Register (WRSR)

The WRSR instruction is for changing the values of Status Register Bits. Before sending WRSR instruction, the Write Enable (WREN) instruction must be decoded and executed to set the Write Enable Latch (WEL) bit in advance. The WRSR instruction can change the value of Block Protect (BP2, BP1, BP0) bits to define the protected area of memory (as shown in table 2). The WRSR also can set or reset the Status Register Write Disable (SRWD) bit in accordance with Write Protection (WP#) pin signal. The WRSR instruction cannot be executed once the Hardware Protected Mode (HPM) is entered.

The sequence is shown as [Figure 14](#).

The WRSR instruction has no effect on b6, b5, b1, b0 of the status register.

The CS# must go high exactly at the byte boundary; otherwise, the instruction will be rejected and not executed. The self-timed Write Status Register cycle time (tW) is initiated as soon as Chip Select (CS#) goes high. The Write in Progress (WIP) bit still can be check out during the Write Status Register cycle is in progress. The WIP sets 1 during the tW timing, and sets 0 when Write Status Register Cycle is completed, and the Write Enable Latch (WEL) bit is reset.

**Table 4. Protection Modes**

| Mode                           | Status register condition                                                                           | WP# and SRWD bit status                                                  | Memory                                         |
|--------------------------------|-----------------------------------------------------------------------------------------------------|--------------------------------------------------------------------------|------------------------------------------------|
| Software protection mode (SPM) | Status register can be written in (WEL bit is set to "1") and the SRWD, BP2-BP0 bits can be changed | WP#=1 and SRWD bit=0, or<br>WP#=0 and SRWD bit=0, or<br>WP#=1 and SRWD=1 | The protected area cannot be program or erase. |
| Hardware protection mode (HPM) | The SRWD, BP2-BP0 of status register bits cannot be changed                                         | WP#=0, SRWD bit=1                                                        | The protected area cannot be program or erase. |

Note:

1. As defined by the values in the Block Protect (BP2, BP1, BP0) bits of the Status Register, as shown in [Table 2](#).

As the above table showing, the summary of the Software Protected Mode (SPM) and Hardware Protected Mode (HPM).

Software Protected Mode (SPM):

- When SRWD bit=0, no matter WP# is low or high, the WREN instruction may set the WEL bit and can change the values of SRWD, BP2, BP1, BP0. The protected area, which is defined by BP2, BP1, BP0, is at software protected mode (SPM).
- When SRWD bit=1 and WP# is high, the WREN instruction may set the WEL bit can change the values of SRWD, BP2, BP1, BP0. The protected area, which is defined by BP2, BP1, BP0, is at software protected mode (SPM).

**Note:** If SRWD bit=1 but WP# is low, it is impossible to write the Status Register even if the WEL bit has previously been set. It is rejected to write the Status Register and not be executed.

Hardware Protected Mode (HPM):

- When SRWD bit=1, and then WP# is low (or WP# is low before SRWD bit=1), it enters the hardware protected mode (HPM). The data of the protected area is protected by software protected mode by BP2, BP1, BP0 and hardware protected mode by the WP# to against data modification.

**Note:** to exit the hardware protected mode requires WP# driving high once the hardware protected mode is entered. If the WP# pin is permanently connected to high, the hardware protected mode can never be entered; only can use software protected mode via BP2, BP1, BP0.

**(5) Read Data Bytes (READ)**

The read instruction is for reading data out. The address is latched on rising edge of SCLK, and data shifts out on the falling edge of SCLK at a maximum frequency  $f_R$ . The first address byte can be at any location. The address is automatically increased to the next higher address after each byte data is shifted out, so the whole memory can be read out at a single READ instruction. The address counter rolls over to 0 when the highest address has been reached.

The sequence is shown as [Figure 15](#).

**(6) Read Data Bytes at Higher Speed (FAST\_READ)**

The FAST\_READ instruction is for quickly reading data out. The address is latched on rising edge of SCLK, and data of each bit shifts out on the falling edge of SCLK at a maximum frequency  $f_C$ . The first address byte can be at any location. The address is automatically increased to the next higher address after each byte data is shifted out, so the whole memory can be read out at a single FAST\_READ instruction. The address counter rolls over to 0 when the highest address has been reached.

The sequence is shown as [Figure 16](#).

While Program/Erase/Write Status Register cycle is in progress, FAST\_READ instruction is rejected without any impact on the Program/Erase/Write Status Register current cycle.

**(7) Dual Output Mode (DREAD)**

The DREAD instruction enable double throughput of Serial Flash in read mode. The address is latched on rising edge of SCLK, and data of every two bits(interleave on 1I/2O pins) shift out on the falling edge of SCLK at a maximum frequency  $f_T$ . The first address byte can be at any location. The address is automatically increased to the next higher address after each byte data is shifted out, so the whole memory can be read out at a single DREAD instruction. The address counter rolls over to 0 when the highest address has been reached. Once writing DREAD instruction, the following address/dummy/data out will perform as 2-bit instead of previous 1-bit.

The sequence is shown as [Figure 17](#).

While Program/Erase/Write Status Register cycle is in progress, DREAD instruction is rejected without any impact on the Program/Erase/Write Status Register current cycle.

The DREAD only perform read operation. Program/Erase /Read ID/Read status....operation do not support DREAD throughputs.

**(8) Sector Erase (SE)**

The Sector Erase (SE) instruction is for erasing the data of the chosen sector to be "1". A Write Enable (WREN) instruction must execute to set the Write Enable Latch (WEL) bit before sending the Sector Erase (SE). Any address of the sector (see table 1) is a valid address for Sector Erase (SE) instruction. The CS# must go high exactly at the byte boundary (the latest eighth of address byte been latched-in); otherwise, the instruction will be rejected and not executed.

Address bits [Am-A12] (Am is the most significant address) select the sector address.

The sequence is shown as [Figure 18](#).

The self-timed Sector Erase Cycle time (tSE) is initiated as soon as Chip Select (CS#) goes high. The Write in Progress (WIP) bit still can be check out during the Sector Erase cycle is in progress. The WIP sets 1 during the tSE timing, and sets 0 when Sector Erase Cycle is completed, and the Write Enable Latch (WEL) bit is reset. If the page is protected by BP2, BP1, BP0 bits, the Sector Erase (SE) instruction will not be executed on the page.

#### **(9) Block Erase (BE)**

The Block Erase (BE) instruction is for erasing the data of the chosen block to be "1". A Write Enable (WREN) instruction must execute to set the Write Enable Latch (WEL) bit before sending the Block Erase (BE). Any address of the block (see table 1) is a valid address for Block Erase (BE) instruction. The CS# must go high exactly at the byte boundary (the latest eighth of address byte been latched-in); otherwise, the instruction will be rejected and not executed.

The sequence is shown as [Figure 19](#).

The self-timed Block Erase Cycle time (tBE) is initiated as soon as Chip Select (CS#) goes high. The Write in Progress (WIP) bit still can be check out during the Sector Erase cycle is in progress. The WIP sets 1 during the tBE timing, and sets 0 when Sector Erase Cycle is completed, and the Write Enable Latch (WEL) bit is reset. If the page is protected by BP2, BP1, BP0 bits, the Block Erase (BE) instruction will not be executed on the page.

#### **(10) Chip Erase (CE)**

The Chip Erase (CE) instruction is for erasing the data of the whole chip to be "1". A Write Enable (WREN) instruction must execute to set the Write Enable Latch (WEL) bit before sending the Chip Erase (CE). Any address of the sector (see table 1) is a valid address for Chip Erase (CE) instruction. The CS# must go high exactly at the byte boundary( the latest eighth of address byte been latched-in); otherwise, the instruction will be rejected and not executed.

The sequence is shown as [Figure 20](#).

The self-timed Chip Erase Cycle time (tCE) is initiated as soon as Chip Select (CS#) goes high. The Write in Progress (WIP) bit still can be check out during the Chip Erase cycle is in progress. The WIP sets 1 during the tCE timing, and sets 0 when Chip Erase Cycle is completed, and the Write Enable Latch (WEL) bit is reset. If the chip is protected by BP2, BP1, BP0 bits, the Chip Erase (CE) instruction will not be executed. It will be only executed when BP2, BP1, BP0 all set to "0".

#### **(11) Page Program (PP)**

The Page Program (PP) instruction is for programming the memory to be "0". A Write Enable (WREN) instruction must execute to set the Write Enable Latch (WEL) bit before sending the Page Program (PP). The device programs only the last 256 data bytes sent to the device. If the entire 256 data bytes are going to be programmed, A7-A0 (The eight least significant address bits) should be set to 0. If the eight least significant address bits (A7-A0) are not all 0, all transmitted data going beyond the end of the current page are programmed from the start address of the same page (from the address A7-A0 are all 0). If more than 256 bytes are sent to the device, the data of the last 256-byte is programmed at the request page and previous data will be disregarded. If less than 256 bytes are sent to the device, the data is programmed at the requested address of the page without effect on other address of the same page.



The sequence is shown as [Figure 21](#).

The CS# must be kept to low during the whole Page Program cycle; The CS# must go high exactly at the byte boundary( the latest eighth bit of data being latched in), otherwise the instruction will be rejected and will not be executed.

The self-timed Page Program Cycle time (tPP) is initiated as soon as Chip Select (CS#) goes high. The Write in Progress (WIP) bit still can be check out during the Page Program cycle is in progress. The WIP sets 1 during the tPP timing, and sets 0 when Page Program Cycle is completed, and the Write Enable Latch (WEL) bit is reset. If the page is protected by BP2, BP1, BP0 bits, the Page Program (PP) instruction will not be executed.

### **(12) Deep Power-down (DP)**

The Deep Power-down (DP) instruction is for setting the device on the minimizing the power consumption (to entering the Deep Power-down mode), the standby current is reduced from ISB1 to ISB2). The Deep Power-down mode requires the Deep Power-down (DP) instruction to enter, during the Deep Power-down mode, the device is not active and all Write/Program/Erase instruction are ignored. When CS# goes high, it's only in standby mode not deep power-down mode. It's different from Standby mode.

The sequence is shown as [Figure 22](#).

Once the DP instruction is set, all instruction will be ignored except the Release from Deep Power-down mode (RDP) and Read Electronic Signature (RES) instruction. (RES instruction to allow the ID been read out). When Power-down, the deep power-down mode automatically stops, and when power-up, the device automatically is in standby mode. For RDP instruction the CS# must go high exactly at the byte boundary (the latest eighth bit of instruction code been latched-in); otherwise, the instruction will not executed. As soon as Chip Select (CS#) goes high, a delay of tDP is required before entering the Deep Power-down mode and reducing the current to ISB2.

### **(13) Release from Deep Power-down (RDP), Read Electronic Signature (RES)**

The Release from Deep Power-down (RDP) instruction is terminated by driving Chip Select (CS#) High. When Chip Select (CS#) is driven High, the device is put in the Stand-by Power mode. If the device was not previously in the Deep Power-down mode, the transition to the Stand-by Power mode is immediate. If the device was previously in the Deep Power-down mode, though, the transition to the Stand-by Power mode is delayed by tRES2, and Chip Select (CS#) must remain High for at least tRES2(max), as specified in [Table 7](#). Once in the Stand-by Power mode, the device waits to be selected, so that it can receive, decode and execute instructions.

RES instruction is for reading out the old style of 8-bit Electronic Signature, whose values are shown as table of ID Definitions. This is not the same as RDID instruction. It is not recommended to use for new design. For new deisng, please use RDID instruction. Even in Deep power-down mode, the RDP and RES are also allowed to be executed, only except the device is in progress of program/erase/write cycle; there's no effect on the current program/erase/write cycle in progress.

The sequence is shown as [Figure 23](#) and [Figure 24](#).

The RES instruction is ended by CS# goes high after the ID been read out at least once. The ID outputs repeatedly if continuously send the additional clock cycles on SCLK while CS# is at low. If the device was not previously in Deep Power-down mode, the device transition to standby mode is immediate. If the device was previously in Deep Power-down mode, there's a delay of tRES2 to transit to standby mode, and CS# must remain to high at least tRES2(max). Once in the standby mode, the device waits to be selected, so it can be receive, decode, and execute instruction.

The RDP instruction is for releasing from Deep Power Down Mode.

#### (14) Read Identification (RDID)

The RDID instruction is for reading the manufacturer ID of 1-byte and followed by Device ID of 2-byte. The MXIC Manufacturer ID is C2(hex), the memory type ID is 20(hex) as the first-byte device ID, and the individual device ID of second-byte ID is as followings: 13(hex) for MX25L4006E.

The sequence is shown as [Figure 25](#).

While Program/Erase operation is in progress, it will not decode the RDID instruction, so there's no effect on the cycle of program/erase operation which is currently in progress. When CS# goes high, the device is at standby stage.

#### (15) Read Electronic Manufacturer ID & Device ID (REMS)

The REMS instruction is an alternative to the Release from Power-down/Device ID instruction that provides both the JEDEC assigned manufacturer ID and the specific device ID.

The REMS instruction is very similar to the Release from Power-down/Device ID instruction. The instruction is initiated by driving the CS# pin low and shift the instruction code "90h" followed by two dummy bytes and one bytes address (A7~A0). After which, the Manufacturer ID for MXIC (C2h) and the Device ID are shifted out on the falling edge of SCLK with most significant bit (MSB) first as shown in [Figure 26](#). The Device ID values are listed in Table 5. ID Definitions. If the one-byte address is initially set to 01h, then the device ID will be read first and then followed by the Manufacturer ID. The Manufacturer and Device IDs can be read continuously, alternating from one to the other. The instruction is completed by driving CS# high.

**Table 5. ID Definitions**

| Command Type | MX25L4006E      |             |                |
|--------------|-----------------|-------------|----------------|
| RDID Command | manufacturer ID | memory type | memory density |
|              | C2              | 20          | 13             |
| RES Command  | electronic ID   |             |                |
|              | 12              |             |                |
| REMS Command | manufacturer ID |             | device ID      |
|              | C2              |             | 12             |

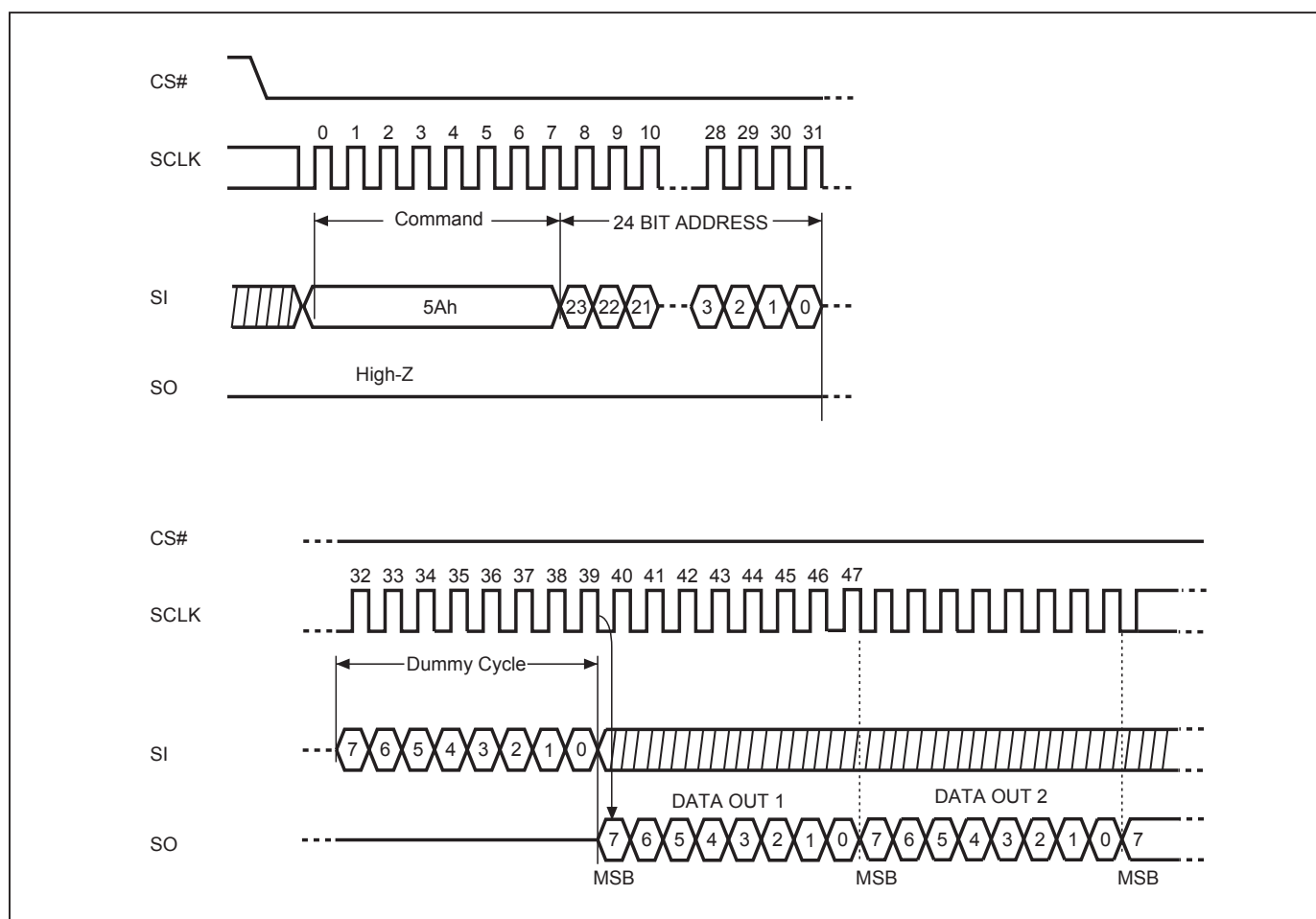
## (16) Read SFDP Mode (RDSFDP)

The Serial Flash Discoverable Parameter (SFDP) standard provides a consistent method of describing the functional and feature capabilities of serial flash devices in a standard set of internal parameter tables. These parameter tables can be interrogated by host system software to enable adjustments needed to accommodate divergent features from multiple vendors. The concept is similar to the one found in the Introduction of JEDEC Standard, JESD68 on CFI.

The sequence of issuing RDSFDP instruction is CS# goes low→send RDSFDP instruction (5Ah)→send 3 address bytes on SI pin→send 1 dummy byte on SI pin→read SFDP code on SO→to end RDSFDP operation can use CS# to high at any time during data out.

SFDP is a standard of JEDEC. JESD216. v1.0.

### Read Serial Flash Discoverable Parameter (RDSFDP) Sequence



**Table a. Signature and Parameter Identification Data Values**

| Description                                | Comment                                         | Add (h)<br>(Byte) | DW Add<br>(Bit) | Data (h/b)<br>(Note1) | Data<br>(h) |
|--------------------------------------------|-------------------------------------------------|-------------------|-----------------|-----------------------|-------------|
| SFDP Signature                             | Fixed: 50444653h                                | 00h               | 07:00           | 53h                   | 53h         |
|                                            |                                                 | 01h               | 15:08           | 46h                   | 46h         |
|                                            |                                                 | 02h               | 23:16           | 44h                   | 44h         |
|                                            |                                                 | 03h               | 31:24           | 50h                   | 50h         |
| SFDP Minor Revision Number                 | Start from 00h                                  | 04h               | 07:00           | 00h                   | 00h         |
| SFDP Major Revision Number                 | Start from 01h                                  | 05h               | 15:08           | 01h                   | 01h         |
| Number of Parameter Headers                | Start from 01h                                  | 06h               | 23:16           | 01h                   | 01h         |
| Unused                                     |                                                 | 07h               | 31:24           | FFh                   | FFh         |
| ID number (JEDEC)                          | 00h: it indicates a JEDEC specified header.     | 08h               | 07:00           | 00h                   | 00h         |
| Parameter Table Minor Revision Number      | Start from 00h                                  | 09h               | 15:08           | 00h                   | 00h         |
| Parameter Table Major Revision Number      | Start from 01h                                  | 0Ah               | 23:16           | 01h                   | 01h         |
| Parameter Table Length<br>(in double word) | How many DWORDs in the Parameter table          | 0Bh               | 31:24           | 09h                   | 09h         |
| Parameter Table Pointer (PTP)              | First address of JEDEC Flash Parameter table    | 0Ch               | 07:00           | 30h                   | 30h         |
|                                            |                                                 | 0Dh               | 15:08           | 00h                   | 00h         |
|                                            |                                                 | 0Eh               | 23:16           | 00h                   | 00h         |
| Unused                                     |                                                 | 0Fh               | 31:24           | FFh                   | FFh         |
| ID number<br>(Macronix manufacturer ID)    | it indicates Macronix manufacturer ID           | 10h               | 07:00           | C2h                   | C2h         |
| Parameter Table Minor Revision Number      | Start from 00h                                  | 11h               | 15:08           | 00h                   | 00h         |
| Parameter Table Major Revision Number      | Start from 01h                                  | 12h               | 23:16           | 01h                   | 01h         |
| Parameter Table Length<br>(in double word) | How many DWORDs in the Parameter table          | 13h               | 31:24           | 04h                   | 04h         |
| Parameter Table Pointer (PTP)              | First address of Macronix Flash Parameter table | 14h               | 07:00           | 60h                   | 60h         |
|                                            |                                                 | 15h               | 15:08           | 00h                   | 00h         |
|                                            |                                                 | 16h               | 23:16           | 00h                   | 00h         |
| Unused                                     |                                                 | 17h               | 31:24           | FFh                   | FFh         |

**Table b. Parameter Table (0): JEDEC Flash Parameter Tables**

| Description                                                                       | Comment                                                                                                                                      | Add (h)<br>(Byte) | DW Add<br>(Bit) | Data (h/b)<br>(Note1) | Data<br>(h) |
|-----------------------------------------------------------------------------------|----------------------------------------------------------------------------------------------------------------------------------------------|-------------------|-----------------|-----------------------|-------------|
| Block/Sector Erase sizes                                                          | 00: Reserved, 01: 4KB erase,<br>10: Reserved,<br>11: not suport 4KB erase                                                                    | 30h               | 01:00           | 01b                   | E5h         |
| Write Granularity                                                                 | 0: 1Byte, 1: 64Byte or larger                                                                                                                |                   | 02              | 1b                    |             |
| Write Enable Instruction<br>Requested for Writing to Volatile<br>Status Registers | 0: Nonvolatile status bit<br>1: Volatile status bit<br>(BP status register bit)                                                              |                   | 03              | 0b                    |             |
| Write Enable Opcode Select for<br>Writing to Volatile Status Registers            | 0: use 50h opcode,<br>1: use 06h opcode<br>Note: If target flash status register is<br>nonvolatile, then bits 3 and 4 must<br>be set to 00b. |                   | 04              | 0b                    |             |
| Unused                                                                            | Contains 111b and can never be<br>changed                                                                                                    |                   | 07:05           | 111b                  |             |
| 4KB Erase Opcode                                                                  |                                                                                                                                              | 31h               | 15:08           | 20h                   | 20h         |
| (1-1-2) Fast Read (Note2)                                                         | 0=not support 1=support                                                                                                                      | 32h               | 16              | 1b                    | 81h         |
| Address Bytes Number used in<br>addressing flash array                            | 00: 3Byte only, 01: 3 or 4Byte,<br>10: 4Byte only, 11: Reserved                                                                              |                   | 18:17           | 00b                   |             |
| Double Transfer Rate (DTR)<br>Clocking                                            | 0=not support 1=support                                                                                                                      |                   | 19              | 0b                    |             |
| (1-2-2) Fast Read                                                                 | 0=not support 1=support                                                                                                                      |                   | 20              | 0b                    |             |
| (1-4-4) Fast Read                                                                 | 0=not support 1=support                                                                                                                      |                   | 21              | 0b                    |             |
| (1-1-4) Fast Read                                                                 | 0=not support 1=support                                                                                                                      |                   | 22              | 0b                    |             |
| Unused                                                                            |                                                                                                                                              |                   | 23              | 1b                    |             |
| Unused                                                                            |                                                                                                                                              | 33h               | 31:24           | FFh                   | FFh         |
| Flash Memory Density                                                              |                                                                                                                                              | 37h:34h           | 31:00           | 003FFFFFFh            |             |
| (1-4-4) Fast Read Number of Wait<br>states (Note3)                                | 0 0000b: Wait states (Dummy<br>Clocks) not support                                                                                           | 38h               | 04:00           | 0 0000b               | 00h         |
| (1-4-4) Fast Read Number of<br>Mode Bits (Note4)                                  | 000b: Mode Bits not support                                                                                                                  |                   | 07:05           | 000b                  |             |
| (1-4-4) Fast Read Opcode                                                          |                                                                                                                                              | 39h               | 15:08           | FFh                   | FFh         |
| (1-1-4) Fast Read Number of Wait<br>states                                        | 0 0000b: Wait states (Dummy<br>Clocks) not support                                                                                           | 3Ah               | 20:16           | 0 0000b               | 00h         |
| (1-1-4) Fast Read Number of<br>Mode Bits                                          | 000b: Mode Bits not support                                                                                                                  |                   | 23:21           | 000b                  |             |
| (1-1-4) Fast Read Opcode                                                          |                                                                                                                                              | 3Bh               | 31:24           | FFh                   | FFh         |

| Description                             | Comment                                                                                   | Add (h)<br>(Byte) | DW Add<br>(Bit) | Data (h/b)<br>(Note1) | Data<br>(h) |
|-----------------------------------------|-------------------------------------------------------------------------------------------|-------------------|-----------------|-----------------------|-------------|
| (1-1-2) Fast Read Number of Wait states | 0 0000b: Wait states (Dummy Clocks) not support                                           | 3Ch               | 04:00           | 0 1000b               | 08h         |
| (1-1-2) Fast Read Number of Mode Bits   | 000b: Mode Bits not support                                                               |                   | 07:05           | 000b                  |             |
| (1-1-2) Fast Read Opcode                |                                                                                           | 3Dh               | 15:08           | 3Bh                   | 3Bh         |
| (1-2-2) Fast Read Number of Wait states | 0 0000b: Wait states (Dummy Clocks) not support                                           | 3Eh               | 20:16           | 0 0000b               | 00h         |
| (1-2-2) Fast Read Number of Mode Bits   | 000b: Mode Bits not support                                                               |                   | 23:21           | 000b                  |             |
| (1-2-2) Fast Read Opcode                |                                                                                           | 3Fh               | 31:24           | FFh                   | FFh         |
| (2-2-2) Fast Read                       | 0=not support 1=support                                                                   | 40h               | 00              | 0b                    | EEh         |
| Unused                                  |                                                                                           |                   | 03:01           | 111b                  |             |
| (4-4-4) Fast Read                       | 0=not support 1=support                                                                   |                   | 04              | 0b                    |             |
| Unused                                  |                                                                                           |                   | 07:05           | 111b                  |             |
| Unused                                  |                                                                                           | 43h:41h           | 31:08           | 0xFFh                 | 0xFFh       |
| Unused                                  |                                                                                           | 45h:44h           | 15:00           | 0xFFh                 | 0xFFh       |
| (2-2-2) Fast Read Number of Wait states | 0 0000b: Wait states (Dummy Clocks) not support                                           | 46h               | 20:16           | 0 000b                | 00h         |
| (2-2-2) Fast Read Number of Mode Bits   | 000b: Mode Bits not support                                                               |                   | 23:21           | 000b                  |             |
| (2-2-2) Fast Read Opcode                |                                                                                           | 47h               | 31:24           | FFh                   | FFh         |
| Unused                                  |                                                                                           | 49h:48h           | 15:00           | 0xFFh                 | 0xFFh       |
| (4-4-4) Fast Read Number of Wait states | 0 0000b: Wait states (Dummy Clocks) not support                                           | 4Ah               | 20:16           | 0 0000b               | 00h         |
| (4-4-4) Fast Read Number of Mode Bits   | 000b: Mode Bits not support                                                               |                   | 23:21           | 000b                  |             |
| (4-4-4) Fast Read Opcode                |                                                                                           | 4Bh               | 31:24           | FFh                   | FFh         |
| Sector Type 1 Size                      | Sector/block size = 2 <sup>N</sup> bytes (Note5)<br>0x00b: this sector type doesn't exist | 4Ch               | 07:00           | 0Ch                   | 0Ch         |
| Sector Type 1 erase Opcode              |                                                                                           | 4Dh               | 15:08           | 20h                   | 20h         |
| Sector Type 2 Size                      | Sector/block size = 2 <sup>N</sup> bytes<br>0x00b: this sector type doesn't exist         | 4Eh               | 23:16           | 10h                   | 10h         |
| Sector Type 2 erase Opcode              |                                                                                           | 4Fh               | 31:24           | D8h                   | D8h         |
| Sector Type 3 Size                      | Sector/block size = 2 <sup>N</sup> bytes<br>0x00b: this sector type doesn't exist         | 50h               | 07:00           | 00h                   | 00h         |
| Sector Type 3 erase Opcode              |                                                                                           | 51h               | 15:08           | FFh                   | FFh         |
| Sector Type 4 Size                      | Sector/block size = 2 <sup>N</sup> bytes<br>0x00b: this sector type doesn't exist         | 52h               | 23:16           | 00h                   | 00h         |
| Sector Type 4 erase Opcode              |                                                                                           | 53h               | 31:24           | FFh                   | FFh         |

**Table c. Parameter Table (1): Macronix Flash Parameter Tables**

| Description                                                       | Comment                                                                               | Add (h)<br>(Byte) | DW Add<br>(Bit) | Data (h/b)<br>(Note1) | Data<br>(h) |
|-------------------------------------------------------------------|---------------------------------------------------------------------------------------|-------------------|-----------------|-----------------------|-------------|
| Vcc Supply Maximum Voltage                                        | 2000h=2.000V<br>2700h=2.700V<br>3600h=3.600V                                          | 61h:60h           | 07:00<br>15:08  | 00h<br>36h            | 00h<br>36h  |
| Vcc Supply Minimum Voltage                                        | 1650h=1.650V<br>2250h=2.250V<br>2350h=2.350V<br>2700h=2.700V                          | 63h:62h           | 23:16<br>31:24  | 00h<br>27h            | 00h<br>27h  |
| HW Reset# pin                                                     | 0=not support 1=support                                                               | 65h:64h           | 00              | 0b                    | 4FF6h       |
| HW Hold# pin                                                      | 0=not support 1=support                                                               |                   | 01              | 1b                    |             |
| Deep Power Down Mode                                              | 0=not support 1=support                                                               |                   | 02              | 1b                    |             |
| SW Reset                                                          | 0=not support 1=support                                                               |                   | 03              | 0b                    |             |
| SW Reset Opcode                                                   | Reset Enable (66h) should be issued before Reset command                              |                   | 11:04           | 1111 1111b (FFh)      |             |
| Program Suspend/Resume                                            | 0=not support 1=support                                                               |                   | 12              | 0b                    |             |
| Erase Suspend/Resume                                              | 0=not support 1=support                                                               |                   | 13              | 0b                    |             |
| Unused                                                            |                                                                                       |                   | 14              | 1b                    |             |
| Wrap-Around Read mode                                             | 0=not support 1=support                                                               |                   | 15              | 0b                    |             |
| Wrap-Around Read mode Opcode                                      |                                                                                       | 66h               | 23:16           | FFh                   | FFh         |
| Wrap-Around Read data length                                      | 08h:support 8B wrap-around read<br>16h:8B&16B<br>32h:8B&16B&32B<br>64h:8B&16B&32B&64B | 67h               | 31:24           | FFh                   | FFh         |
| Individual block lock                                             | 0=not support 1=support                                                               | 6Bh:68h           | 00              | 0b                    | CFFEh       |
| Individual block lock bit (Volatile/Nonvolatile)                  | 0=Volatile 1=Nonvolatile                                                              |                   | 01              | 1b                    |             |
| Individual block lock Opcode                                      |                                                                                       |                   | 09:02           | 1111 1111b            |             |
| Individual block lock Volatile protect bit default protect status | 0=protect 1=unprotect                                                                 |                   | 10              | 1b                    |             |
| Secured OTP                                                       | 0=not support 1=support                                                               |                   | 11              | 1b                    |             |
| Read Lock                                                         | 0=not support 1=support                                                               |                   | 12              | 0b                    |             |
| Permanent Lock                                                    | 0=not support 1=support                                                               |                   | 13              | 0b                    |             |
| Unused                                                            |                                                                                       |                   | 15:14           | 11b                   |             |
| Unused                                                            |                                                                                       |                   | 31:16           | 0xFFh                 | 0xFFh       |
| Unused                                                            |                                                                                       | 6Fh:6Ch           | 31:00           | 0xFFh                 | 0xFFh       |

Note 1: h/b is hexadecimal or binary.

Note 2: **(x-y-z)** means I/O mode nomenclature used to indicate the number of active pins used for the opcode (x), address (y), and data (z). At the present time, the only valid Read SFDP instruction modes are: (1-1-1), (2-2-2), and (4-4-4)

Note 3: **Wait States** is required dummy clock cycles after the address bits or optional mode bits.

Note 4: **Mode Bits** is optional control bits that follow the address bits. These bits are driven by the system controller if they are specified. (eg, read performance enhance toggling bits)

Note 5: 4KB=2<sup>0Ch</sup>, 32KB=2<sup>0Fh</sup>, 64KB=2<sup>10h</sup>

Note 6: 0xFFh means all data is blank ("1b").



**POWER-ON STATE**

The device is at below states when power-up:

- Standby mode ( please note it is not deep power-down mode)
- Write Enable Latch (WEL) bit is reset

The device must not be selected during power-up and power-down stage unless the VCC achieves below correct level:

- VCC minimum at power-up stage and then after a delay of tVSL
- GND at power-down

Please note that a pull-up resistor on CS# may ensure a safe and proper power-up/down level.

An internal power-on reset (POR) circuit may protect the device from data corruption and inadvertent data change during power up state.

For further protection on the device, if the VCC does not reach the VCC minimum level, the correct operation is not guaranteed. The write, read, erase, and program command should be sent after the below time delay:

- tVSL after VCC reached VCC minimum level

The device can accept read command after VCC reached VCC minimum and a time delay of tVSL.

Please refer to the figure of "power-up timing".

**Note:**

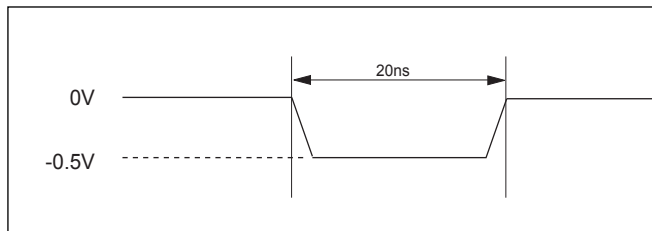
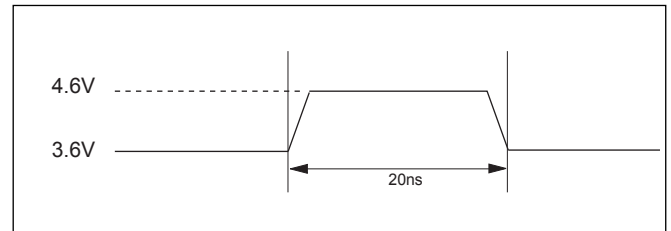
- To stabilize the VCC level, the VCC rail decoupled by a suitable capacitor close to package pins is recommended. (generally around 0.1uF)

**ELECTRICAL SPECIFICATIONS****ABSOLUTE MAXIMUM RATINGS**

| RATING                        |                      | VALUE          |
|-------------------------------|----------------------|----------------|
| Ambient Operating Temperature | Industrial (I) grade | -40°C to 85°C  |
| Storage Temperature           |                      | -55°C to 125°C |
| Applied Input Voltage         |                      | -0.5V to 4.6V  |
| Applied Output Voltage        |                      | -0.5V to 4.6V  |
| VCC to Ground Potential       |                      | -0.5V to 4.6V  |

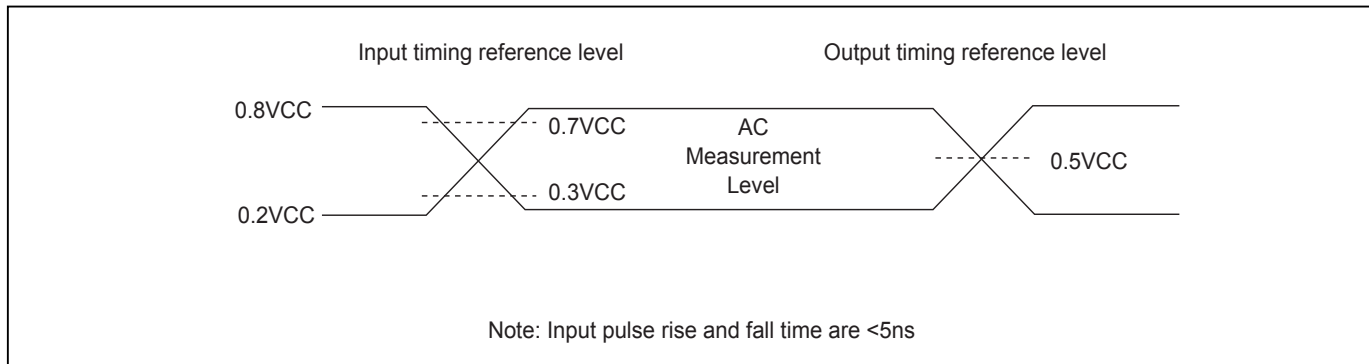
**Notes:**

1. Stresses greater than those listed under ABSOLUTE MAXIMUM RATINGS may cause permanent damage to the device. This is stress rating only and functional operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended period may affect reliability.
2. Specifications contained within the following tables are subject to change.
3. During voltage transitions, all pins may overshoot to 4.6V or -0.5V for period up to 20ns.
4. All input and output pins may overshoot to VCC+0.5V while VCC+0.5V is smaller than or equal to 4.6V.

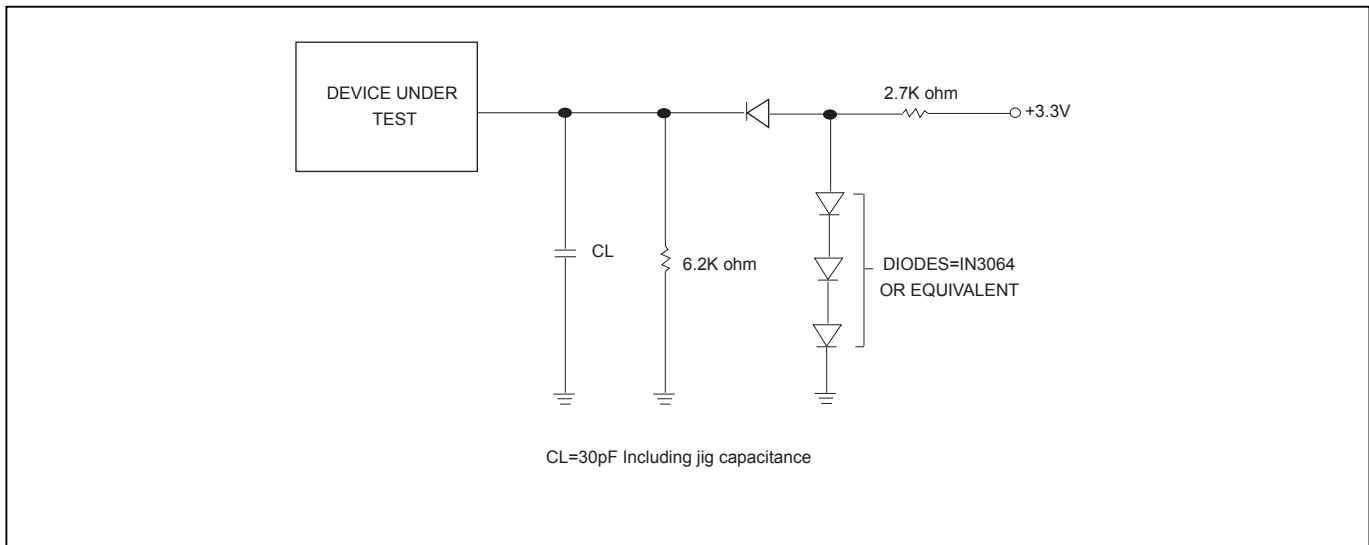
**Figure 3. Maximum Negative Overshoot Waveform****Figure 4. Maximum Positive Overshoot Waveform****CAPACITANCE TA = 25°C, f = 1.0 MHz**

| Symbol | Parameter          | Min. | Typ. | Max. | Unit | Conditions |
|--------|--------------------|------|------|------|------|------------|
| CIN    | Input Capacitance  |      |      | 6    | pF   | VIN = 0V   |
| COUT   | Output Capacitance |      |      | 8    | pF   | VOUT = 0V  |

**Figure 5. INPUT TEST WAVEFORMS AND MEASUREMENT LEVEL**



**Figure 6. OUTPUT LOADING**



**Table 6. DC CHARACTERISTICS** (Temperature = -40°C to 85°C, VCC = 2.7V ~ 3.6V)

| Symbol | Parameter                                | Notes | Min.    | Typ. | Max.    | Units | Test Conditions                              |
|--------|------------------------------------------|-------|---------|------|---------|-------|----------------------------------------------|
| ILI    | Input Load Current                       | 1     |         |      | ± 2     | uA    | VCC = VCC Max<br>VIN = VCC or GND            |
| ILO    | Output Leakage Current                   | 1     |         |      | ± 2     | uA    | VCC = VCC Max<br>VOUT = VCC or GND           |
| ISB1   | VCC Standby Current                      | 1     |         |      | 25      | uA    | VIN = VCC or GND<br>CS# = VCC                |
| ISB2   | Deep Power-down Current                  |       |         | 5    | 10      | uA    | VIN = VCC or GND<br>CS# = VCC                |
| ICC1   | VCC Read                                 | 1     |         |      | 12      | mA    | f=86MHz<br>SCLK=0.1VCC/0.9VCC,<br>SO=Open    |
|        |                                          |       |         |      | 12      | mA    | f=66MHz<br>SCLK=0.1VCC/0.9VCC,<br>SO=Open    |
|        |                                          |       |         |      | 4       | mA    | f=33MHz<br>SCLK=0.1VCC/0.9VCC,<br>SO=Open    |
| ICC2   | VCC Program Current (PP)                 | 1     |         |      | 20      | mA    | Program in Progress<br>CS# = VCC             |
| ICC3   | VCC Write Status Register (WRSR) Current |       |         |      | 15      | mA    | Program status register in progress, CS#=VCC |
| ICC4   | VCC Sector Erase Current (SE)            | 1     |         |      | 15      | mA    | Erase in Progress, CS#=VCC                   |
| ICC5   | VCC Chip Erase Current (CE)              | 1     |         |      | 20      | mA    | Erase in Progress, CS#=VCC                   |
| VIL    | Input Low Voltage                        |       | -0.5    |      | 0.3VCC  | V     |                                              |
| VIH    | Input High Voltage                       |       | 0.7VCC  |      | VCC+0.4 | V     |                                              |
| VOL    | Output Low Voltage                       |       |         |      | 0.4     | V     | IOL = 1.6mA                                  |
| VOH    | Output High Voltage                      |       | VCC-0.2 |      |         | V     | IOH = -100uA                                 |
| VWI    | Low VCC Write Inhibit Voltage            | 3     | 2.1     | 2.3  | 2.5     | V     |                                              |

**Notes:**

1. Typical values at VCC = 3.3V, T = 25°C. These currents are valid for all product versions (package and speeds).
2. Typical value is calculated by simulation.
3. Not 100% tested.

**Table 7. AC CHARACTERISTICS** (Temperature = -40°C to 85°C, VCC = 2.7V ~ 3.6V)

| Symbol   | Alt. | Parameter                                                                                                                           | Min.             | Typ.      | Max.   | Unit     |
|----------|------|-------------------------------------------------------------------------------------------------------------------------------------|------------------|-----------|--------|----------|
| fSCLK    | fC   | Clock Frequency for the following instructions:<br>FAST_READ, RDSFDP, PP, SE, BE, CE, DP, RES,<br>RDP, WREN, WRDI, RDID, RDSR, WRSR | DC               |           | 86     | MHz      |
| fRCLK    | fR   | Clock Frequency for READ instructions                                                                                               | DC               |           | 33     | MHz      |
| fTCLK    | fT   | Clock Frequency for DREAD instructions                                                                                              | DC               |           | 80     | MHz      |
| tCH(1)   | tCLH | Clock High Time                                                                                                                     | @33MHz<br>@86MHz | 13<br>5.5 |        | ns<br>ns |
| tCL(1)   | tCLL | Clock Low Time                                                                                                                      | @33MHz<br>@86MHz | 13<br>5.5 |        | ns<br>ns |
| tCLCH(2) |      | Clock Rise Time (3) (peak to peak)                                                                                                  | 0.1              |           |        | V/ns     |
| tCHCL(2) |      | Clock Fall Time (3) (peak to peak)                                                                                                  | 0.1              |           |        | V/ns     |
| tSLCH    | tCSS | CS# Active Setup Time (relative to SCLK)                                                                                            | 7                |           |        | ns       |
| tCHSL    |      | CS# Not Active Hold Time (relative to SCLK)                                                                                         | 7                |           |        | ns       |
| tDVCH    | tDSU | Data In Setup Time                                                                                                                  | 2                |           |        | ns       |
| tCHDX    | tDH  | Data In Hold Time                                                                                                                   | 5                |           |        | ns       |
| tCHSH    |      | CS# Active Hold Time (relative to SCLK)                                                                                             | 7                |           |        | ns       |
| tSHCH    |      | CS# Not Active Setup Time (relative to SCLK)                                                                                        | 7                |           |        | ns       |
| tSHSL    | tCSH | CS# Deselect Time                                                                                                                   | Read<br>Write    | 15<br>40  |        | ns<br>ns |
| tSHQZ(2) | tDIS | Output Disable Time                                                                                                                 |                  |           | 6      | ns       |
| tCLQV    | tV   | Clock Low to Output Valid                                                                                                           | 30pF<br>15pF     |           | 8<br>6 | ns<br>ns |
| tCLQX    | tHO  | Output Hold Time                                                                                                                    | 0                |           |        | ns       |
| tHLCH    |      | HOLD# Setup Time (relative to SCLK)                                                                                                 | 5                |           |        | ns       |
| tCHHH    |      | HOLD# Hold Time (relative to SCLK)                                                                                                  | 5                |           |        | ns       |
| tHHCH    |      | HOLD Setup Time (relative to SCLK)                                                                                                  | 5                |           |        | ns       |
| tCHHL    |      | HOLD Hold Time (relative to SCLK)                                                                                                   | 5                |           |        | ns       |
| tHHQX(2) | tLZ  | HOLD to Output Low-Z                                                                                                                |                  |           | 6      | ns       |
| tHLQZ(2) | tHZ  | HOLD# to Output High-Z                                                                                                              |                  |           | 6      | ns       |
| tWHSL(4) |      | Write Protect Setup Time                                                                                                            | 20               |           |        | ns       |
| tSHWL(4) |      | Write Protect Hold Time                                                                                                             | 100              |           |        | ns       |
| tDP(2)   |      | CS# High to Deep Power-down Mode                                                                                                    |                  |           | 10     | us       |
| tRES1(2) |      | CS# High to Standby Mode without Electronic Signature Read                                                                          |                  |           | 8.8    | us       |
| tRES2(2) |      | CS# High to Standby Mode with Electronic Signature Read                                                                             |                  |           | 8.8    | us       |
| tW       |      | Write Status Register Cycle Time                                                                                                    |                  | 5         | 40     | ms       |
| tBP      |      | Byte-Program                                                                                                                        |                  | 9         | 300    | us       |
| tPP      |      | Page Program Cycle Time                                                                                                             |                  | 1.4       | 5      | ms       |
| tSE      |      | Sector Erase Cycle Time                                                                                                             |                  | 60        | 300    | ms       |
| tBE      |      | Block Erase Cycle Time                                                                                                              |                  | 0.7       | 2      | s        |
| tCE      |      | Chip Erase Cycle Time                                                                                                               |                  | 3.5       | 7.5    | s        |

**Note:**

1.  $tCH + tCL$  must be greater than or equal to  $1/f$  (fC or fR).
2. Value guaranteed by characterization, not 100% tested in production.
3. Expressed as a slew-rate.
4. Only applicable as a constraint for a WRSR instruction when SRWD is set at 1.
5. Test condition is shown as Figure 5 & 6.
6. The CS# rising time needs to follow tCLCH spec and CS# falling time needs to follow tCHCL spec.

**Table 8. Power-Up Timing**

| Symbol  | Parameter           | Min. | Max. | Unit |
|---------|---------------------|------|------|------|
| tVSL(1) | VCC(min) to CS# low | 200  |      | us   |

**Note:** 1. The parameter is characterized only.

## INITIAL DELIVERY STATE

The device is delivered with the memory array erased: all bits are set to 1 (each byte contains FFh).

### Timing Analysis

Figure 7. Serial Input Timing

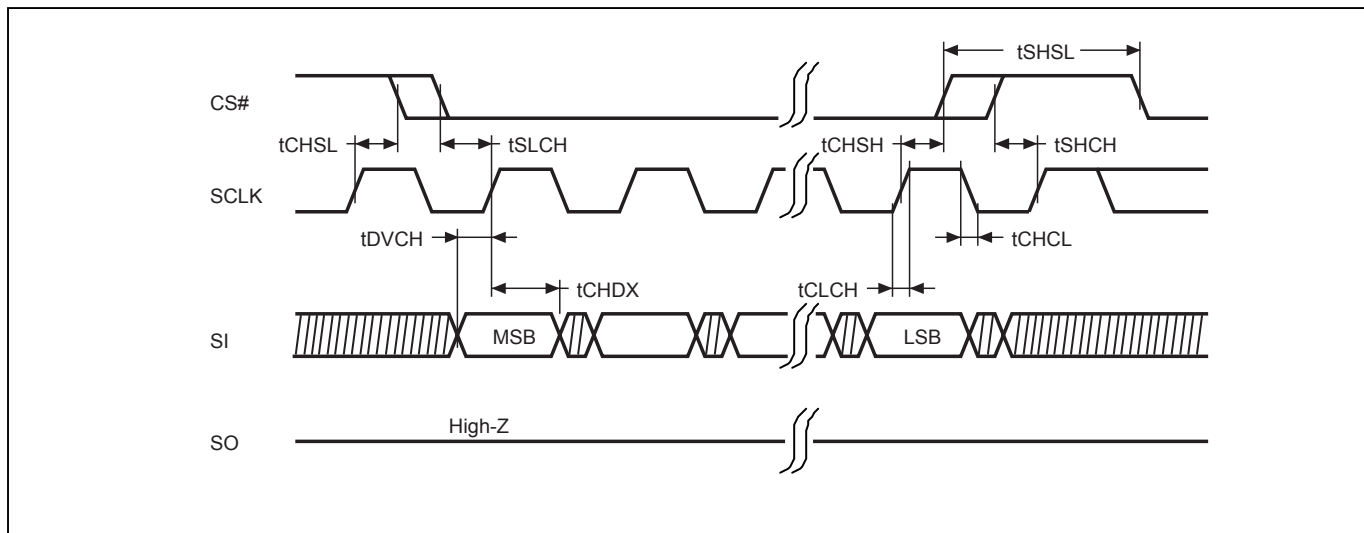


Figure 8. Output Timing

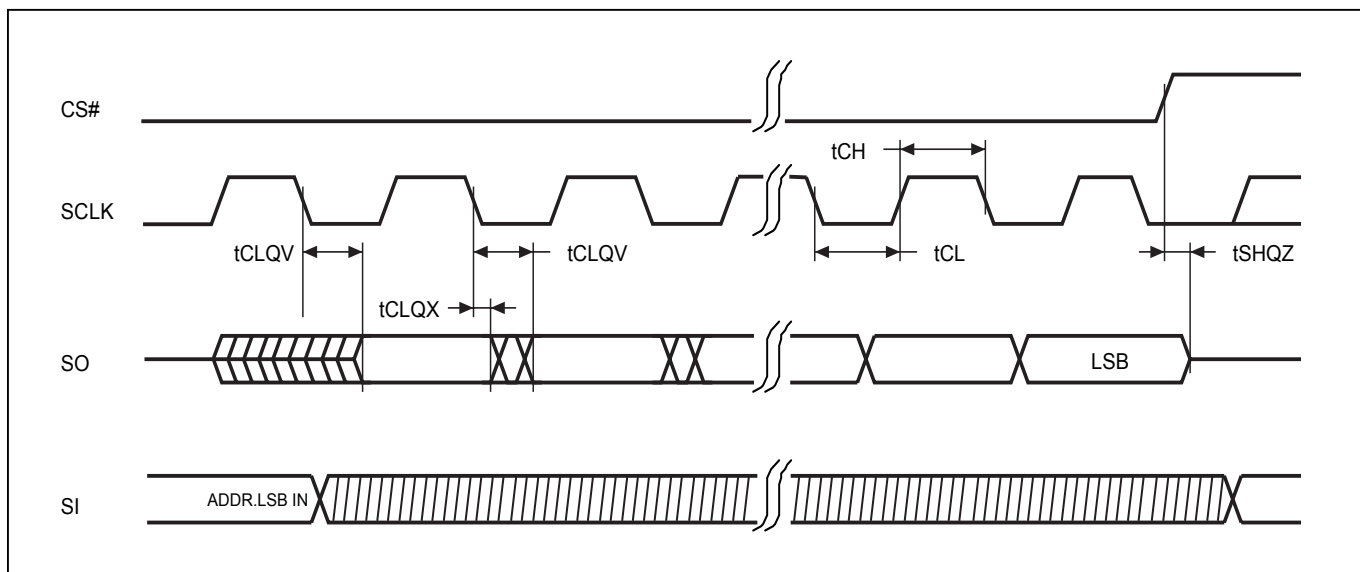
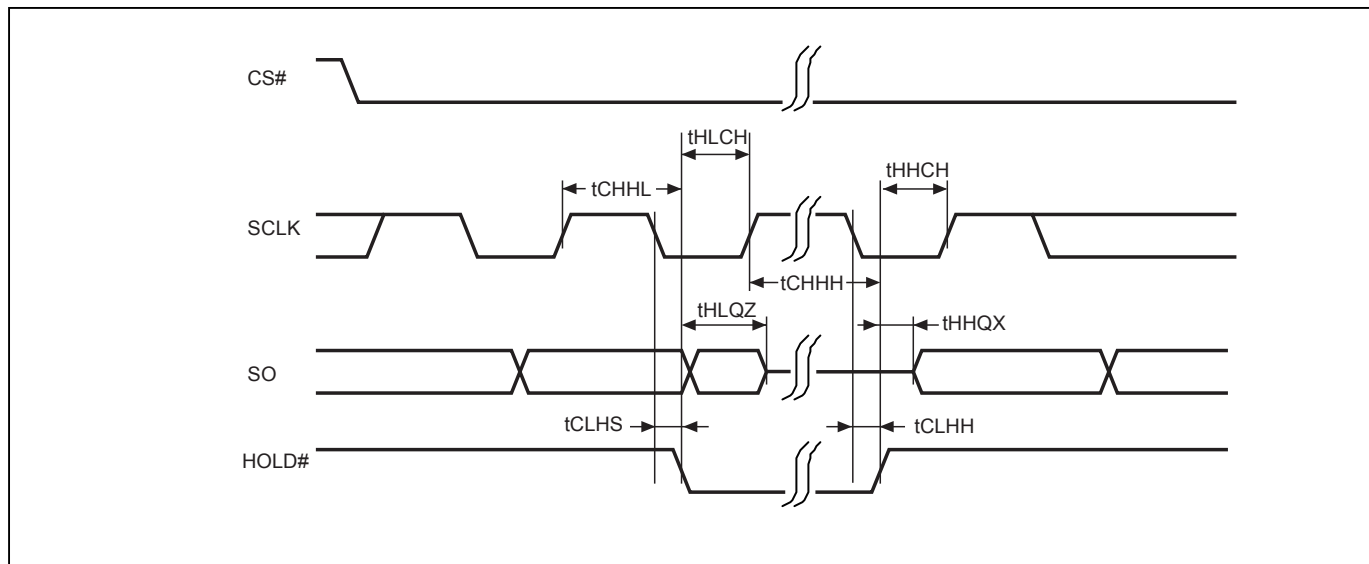
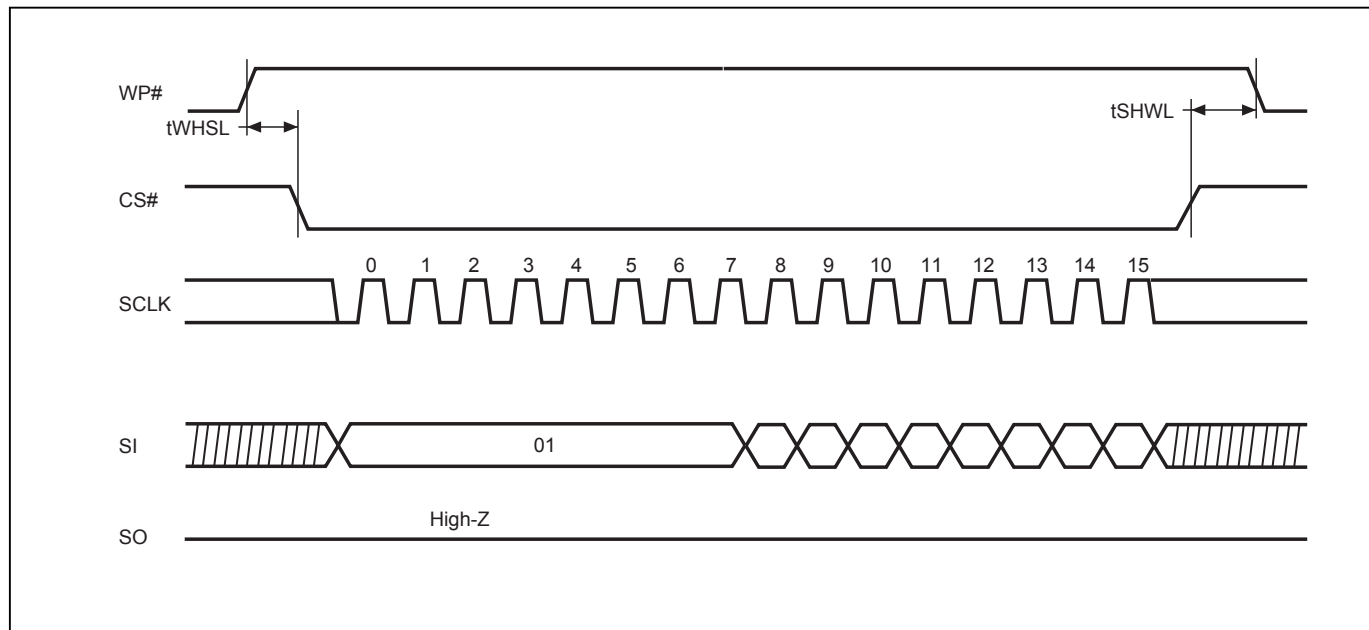


Figure 9. Hold Timing



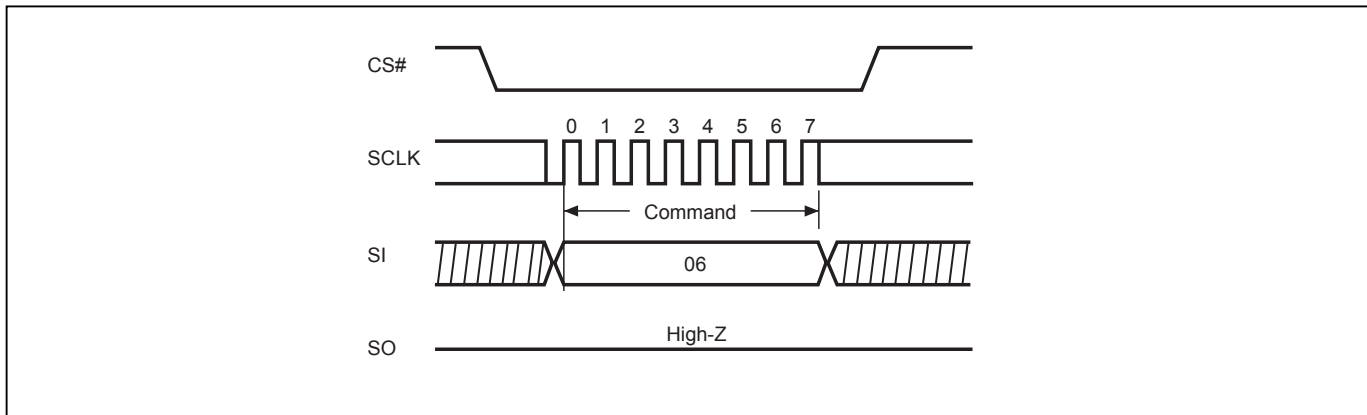
\* SI is "don't care" during HOLD operation.

Figure 10. WP# Disable Setup and Hold Timing during WRSR when SRWD=1

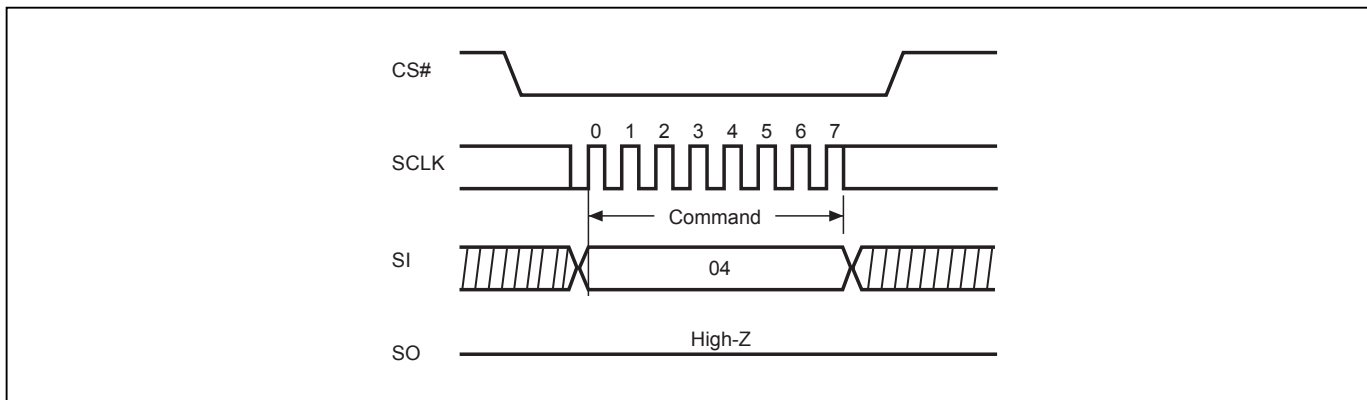




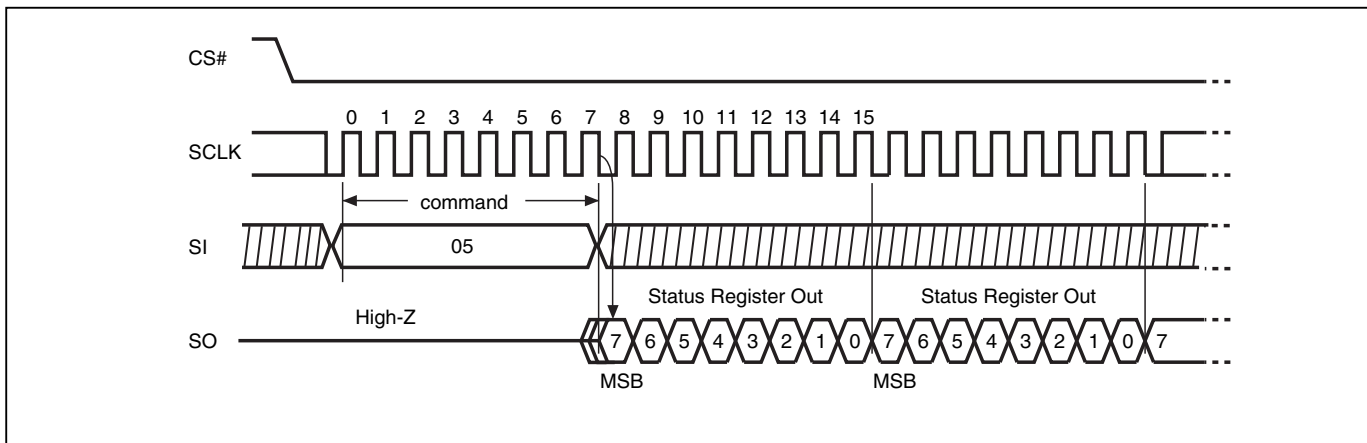
**Figure 11. Write Enable (WREN) Sequence (Command 06)**



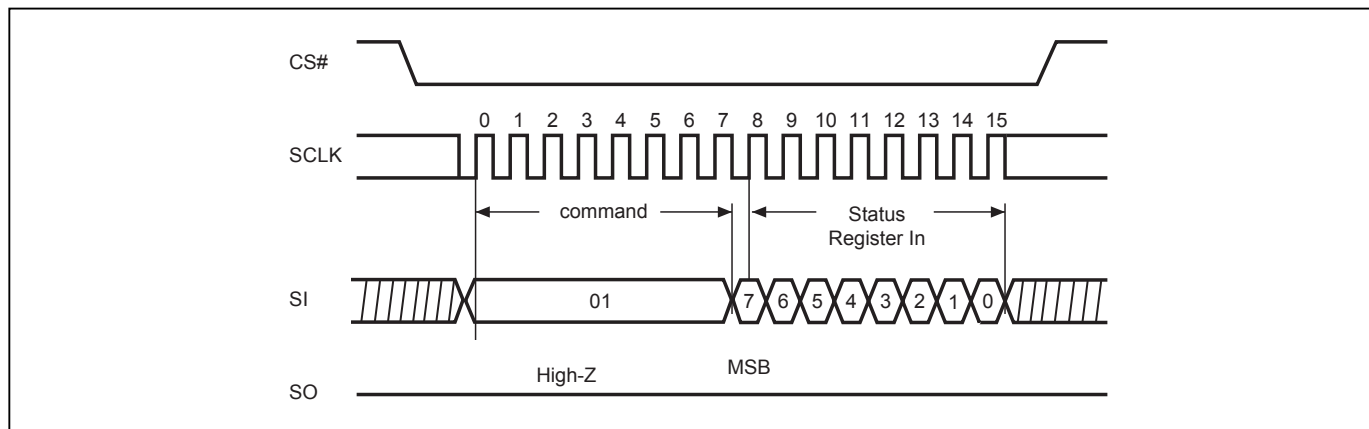
**Figure 12. Write Disable (WRDI) Sequence (Command 04)**



**Figure 13. Read Status Register (RDSR) Sequence (Command 05)**



**Figure 14. Write Status Register (WRSR) Sequence (Command 01)**



**Figure 15. Read Data Bytes (READ) Sequence (Command 03)**

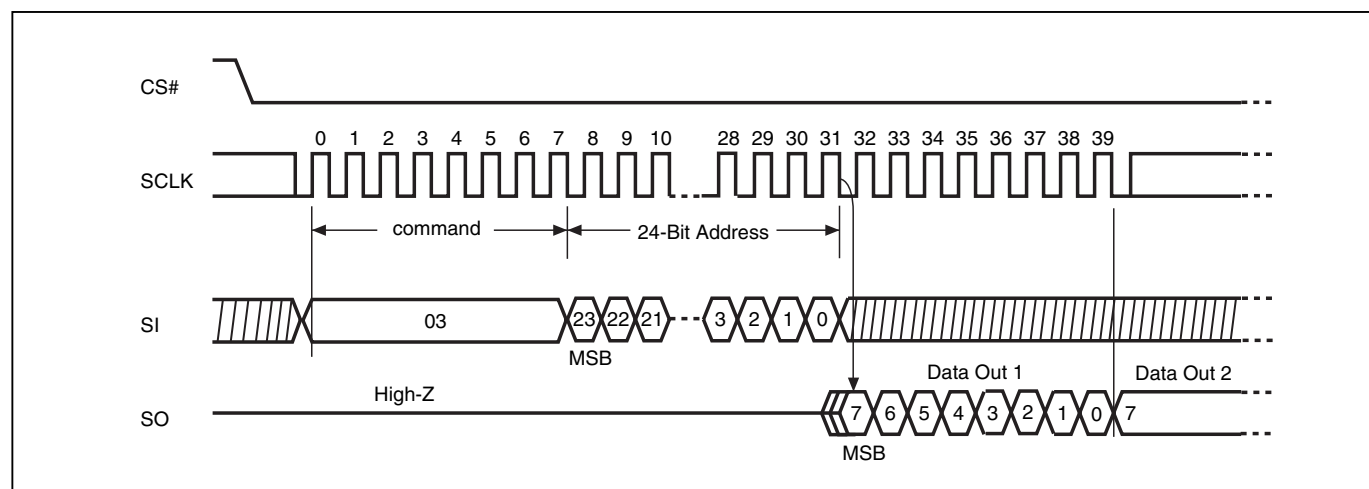


Figure 16. Read at Higher Speed (FAST\_READ) Sequence (Command 0B)

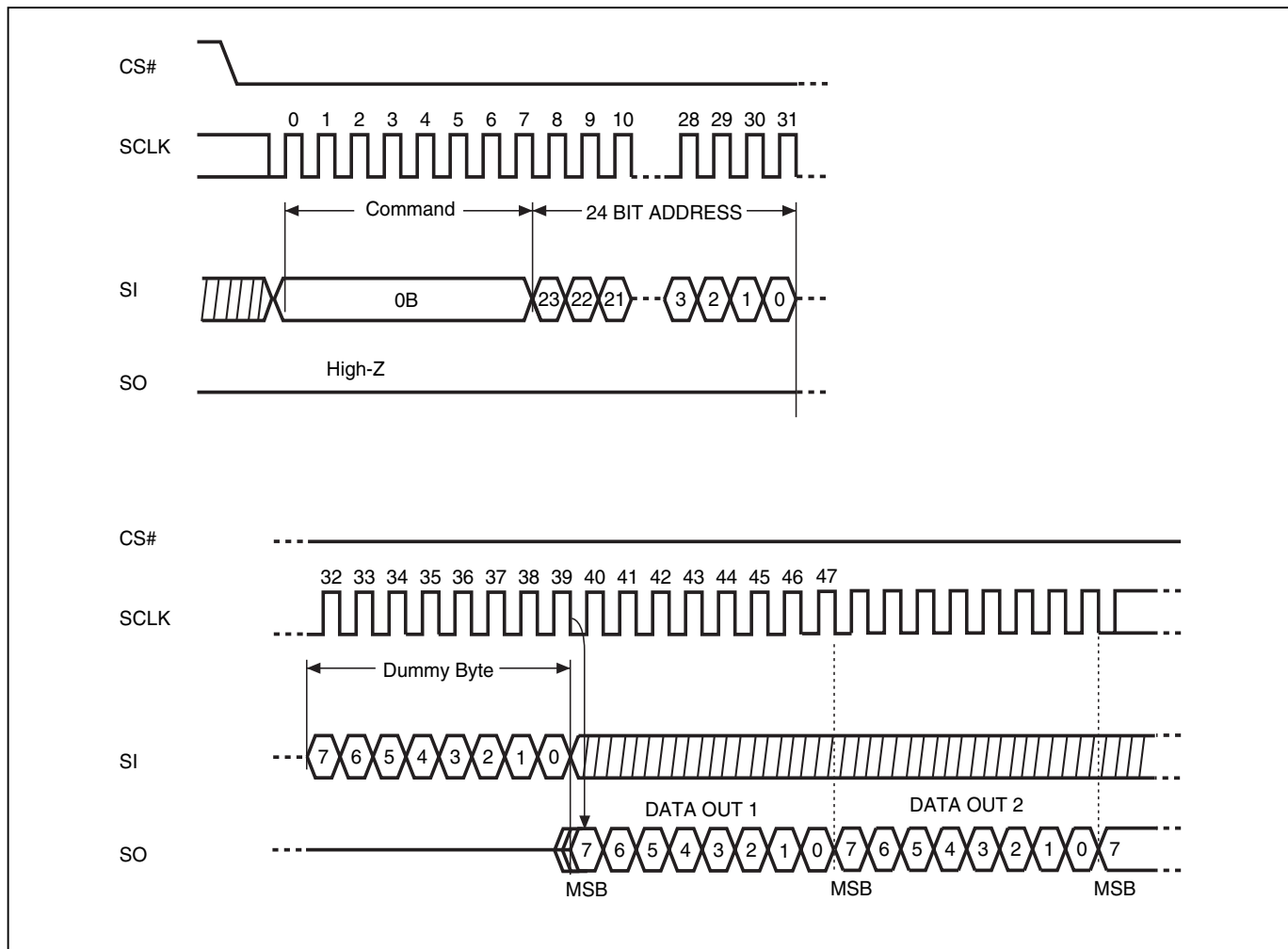
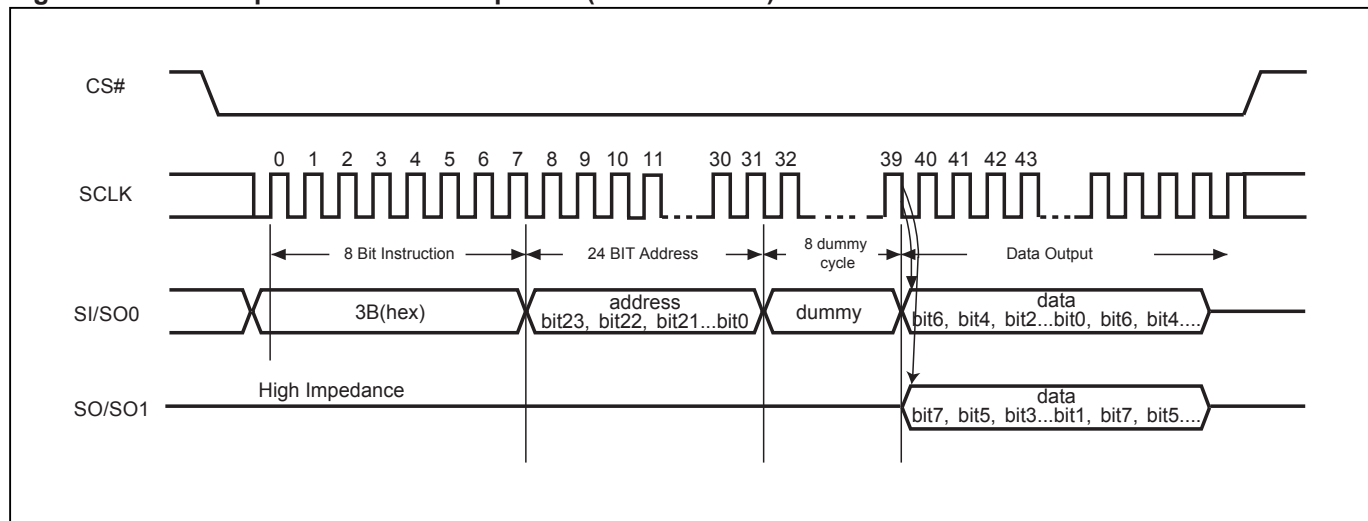
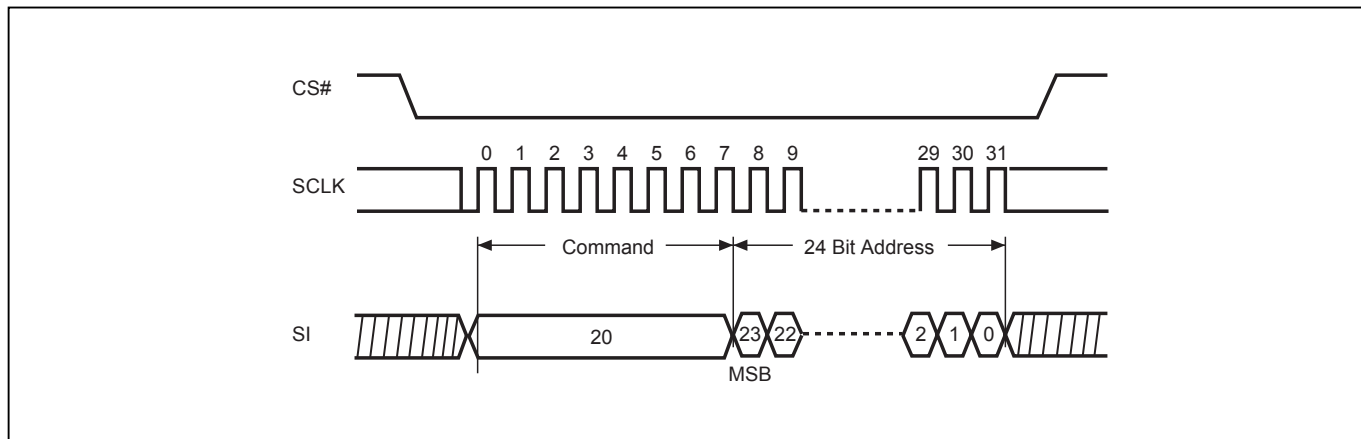


Figure 17. Dual Output Read Mode Sequence (Command 3B)

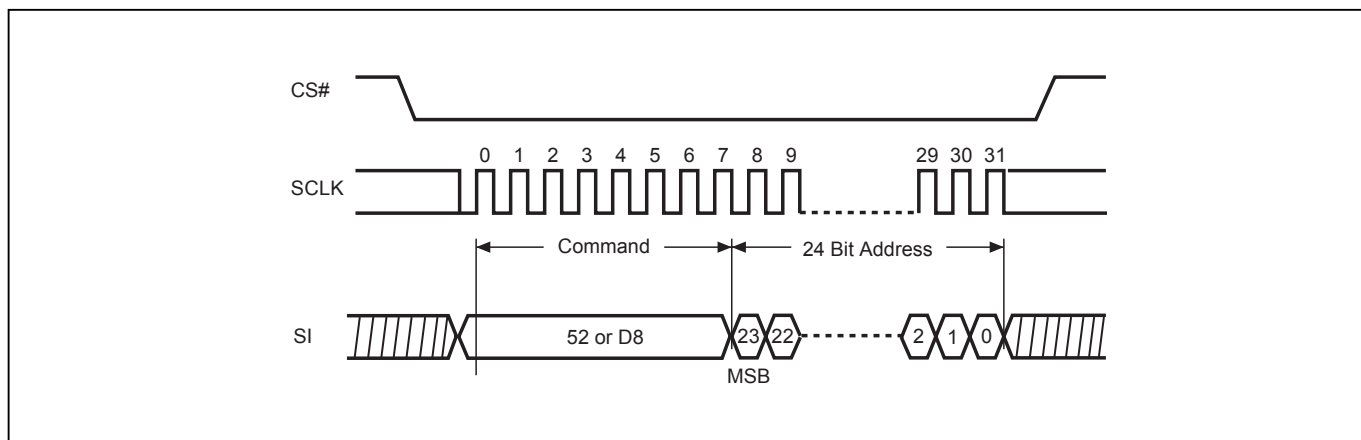


**Figure 18. Sector Erase (SE) Sequence (Command 20)**



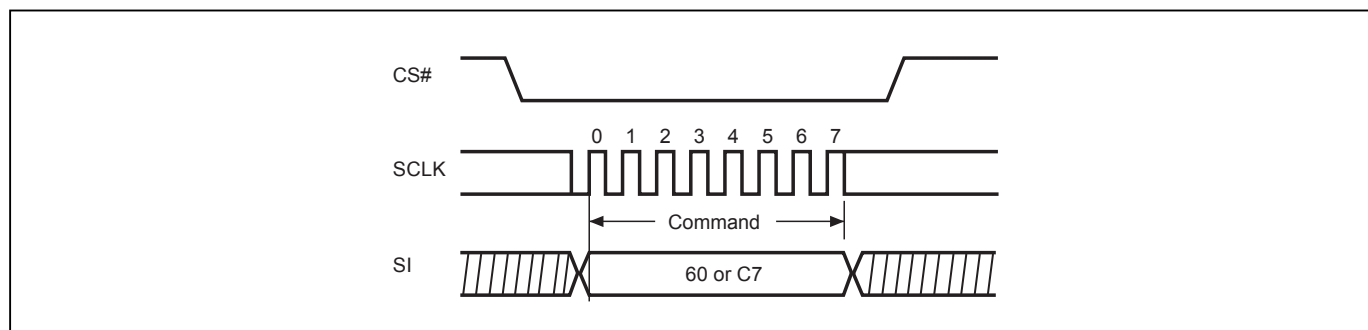
**Note:** SE command is 20(hex).

**Figure 19. Block Erase (BE) Sequence (Command 52 or D8)**



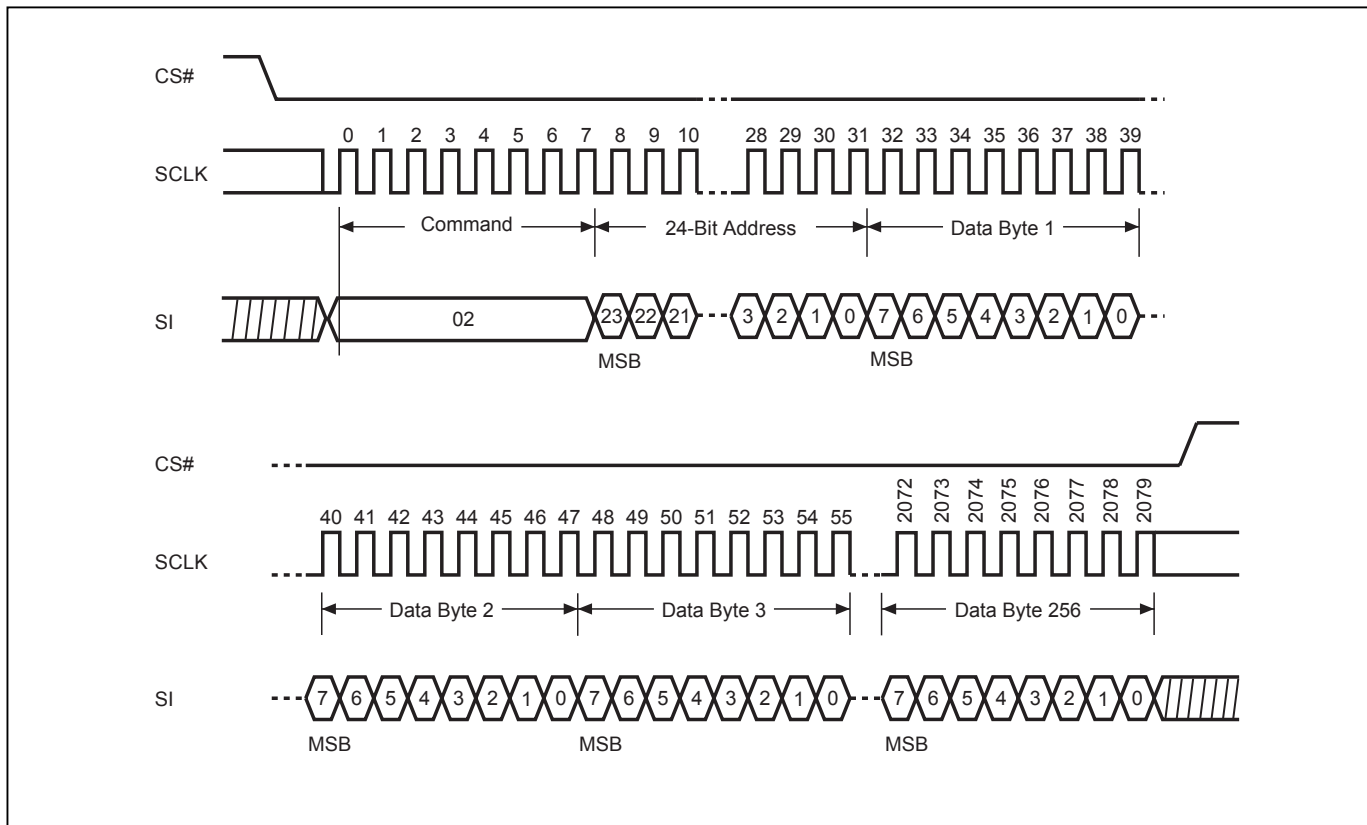
**Note:** BE command is 52 or D8(hex).

**Figure 20. Chip Erase (CE) Sequence (Command 60 or C7)**

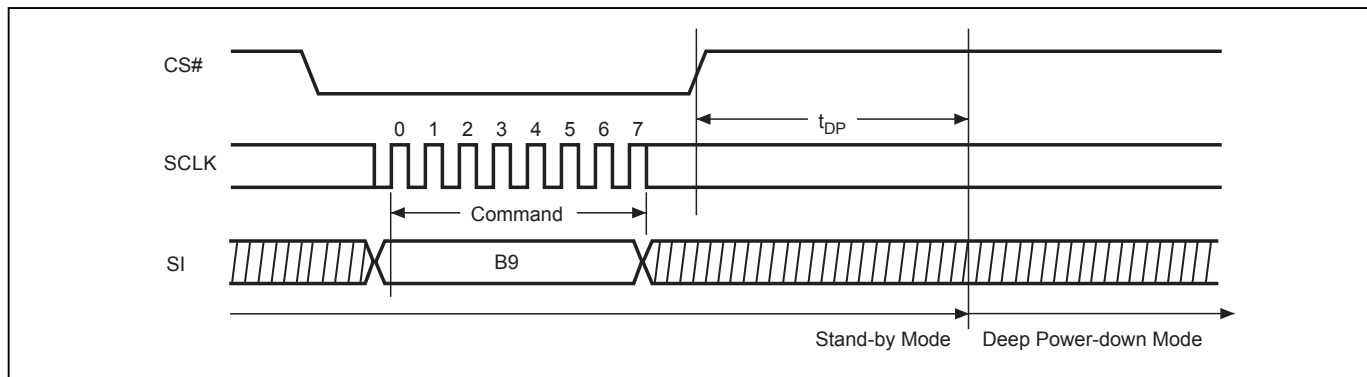


**Note:** CE command is 60(hex) or C7(hex).

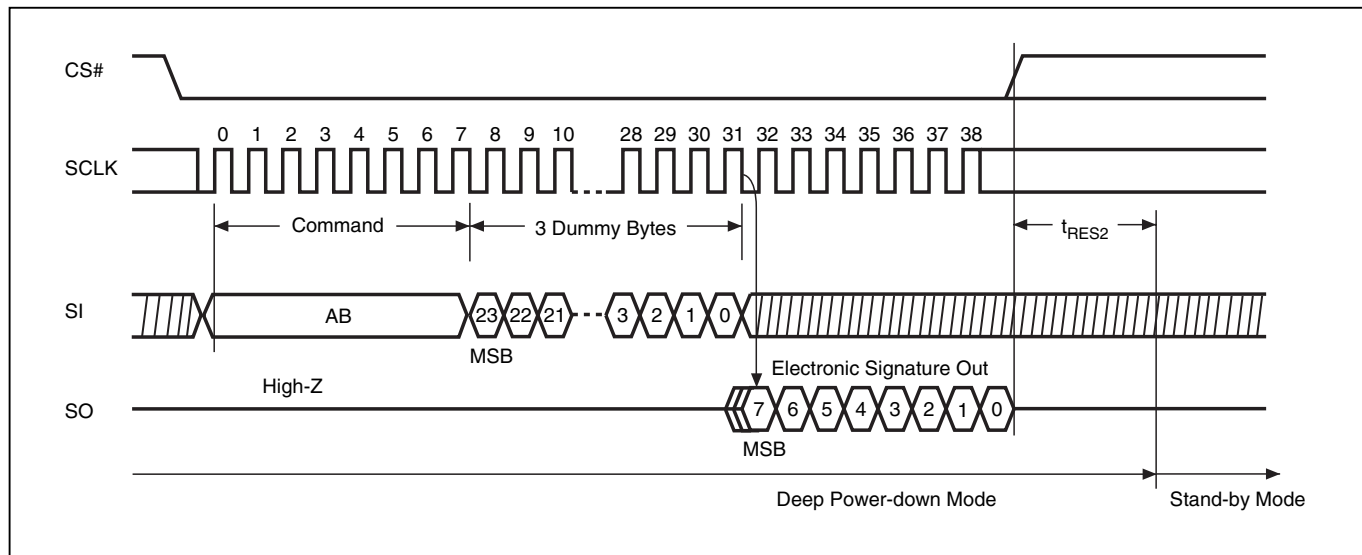
**Figure 21. Page Program (PP) Sequence (Command 02)**



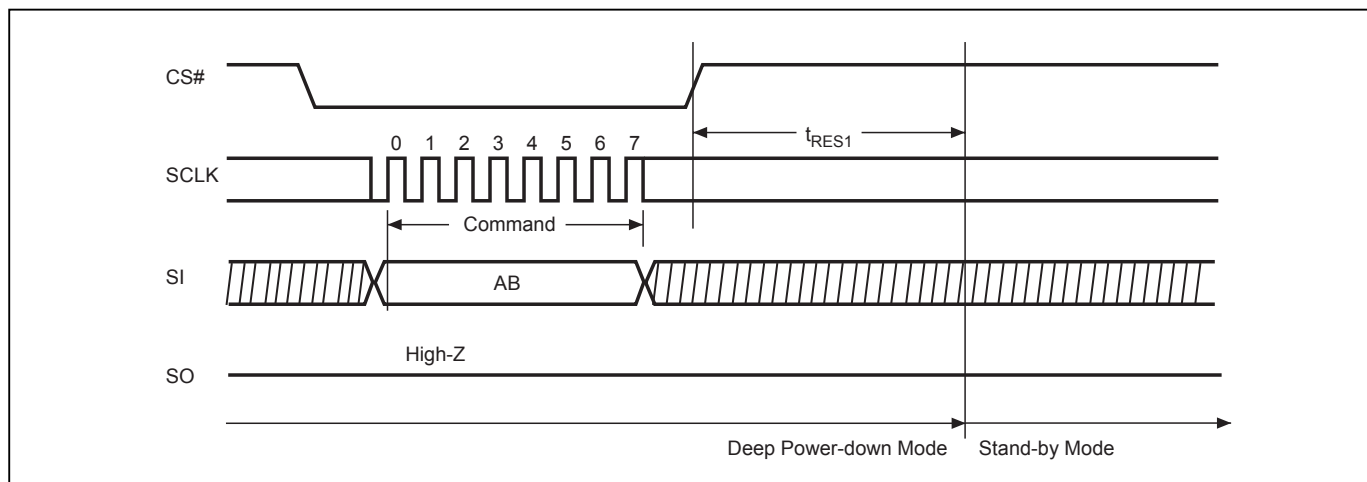
**Figure 22. Deep Power-down (DP) Sequence (Command B9)**



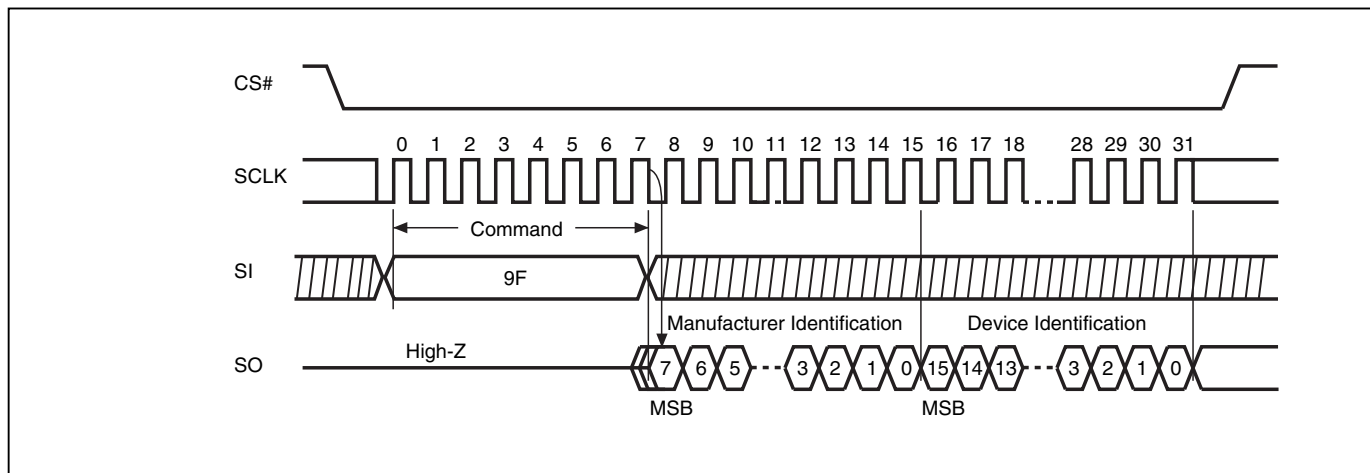
**Figure 23. Read Electronic Signature (RES) Sequence (Command AB)**



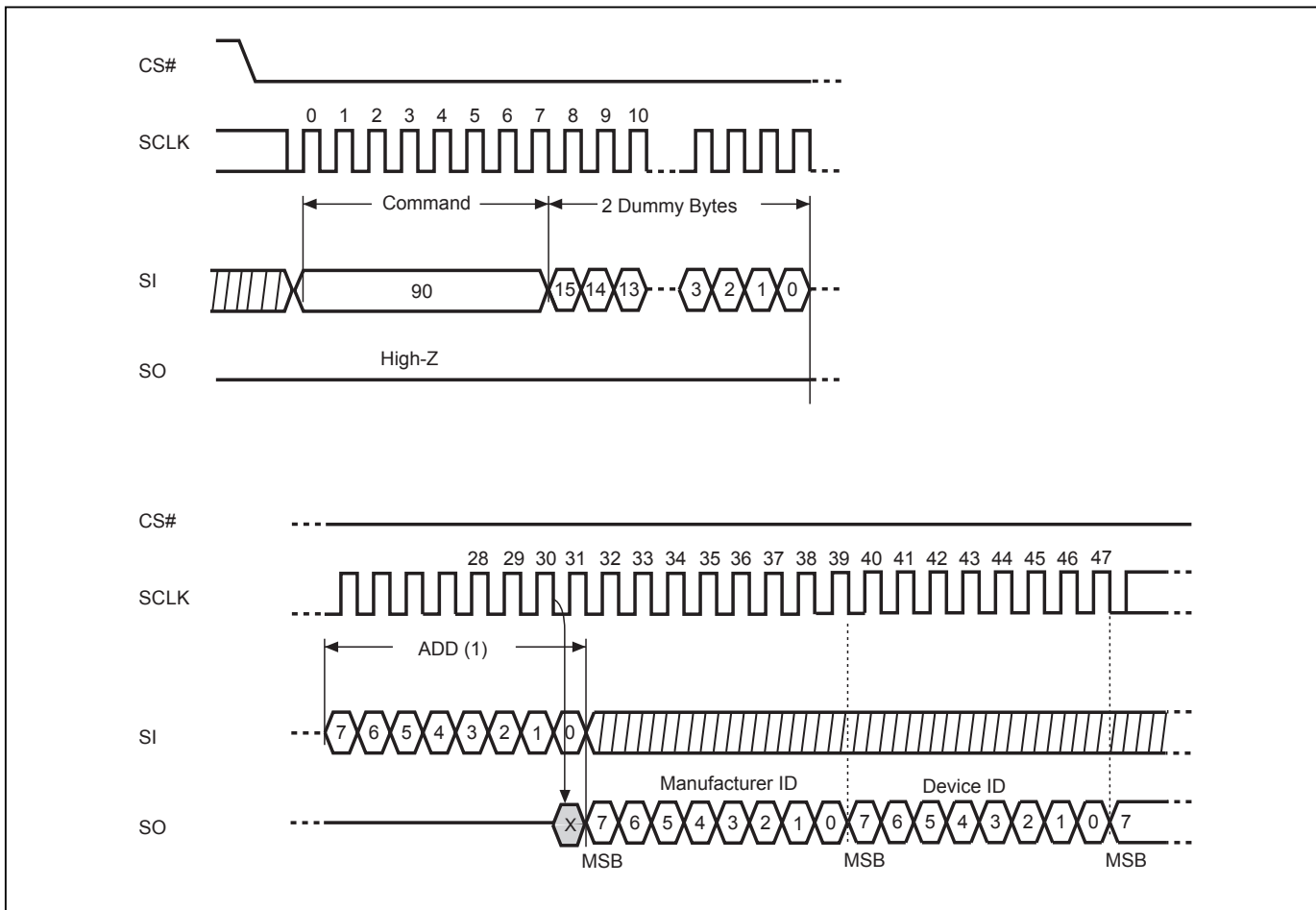
**Figure 24. Release from Deep Power-down (RDP) Sequence (Command AB)**



**Figure 25. Read Identification (RDID) Sequence (Command 9F)**

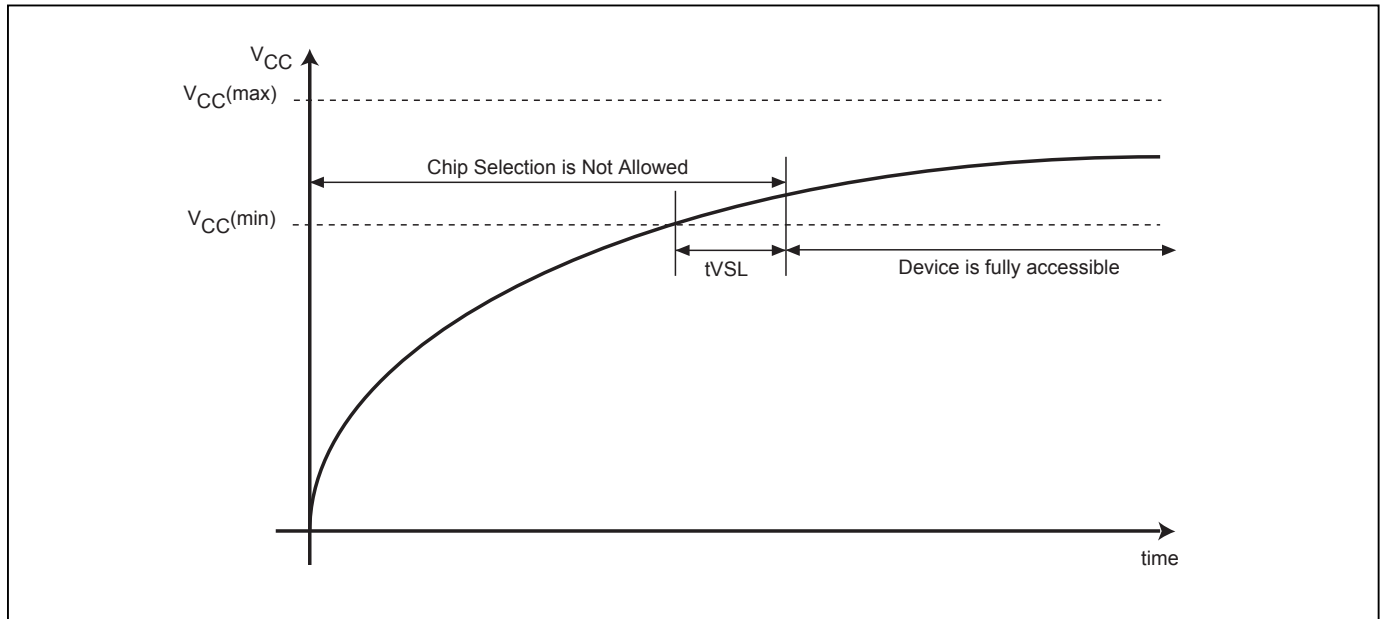


**Figure 26. Read Electronic Manufacturer & Device ID (REMS) Sequence (Command 90)**



**Notes:**

(1) ADD=00H will output the manufacturer's ID first and ADD=01H will output device ID first.

**Figure 27. Power-up Timing**



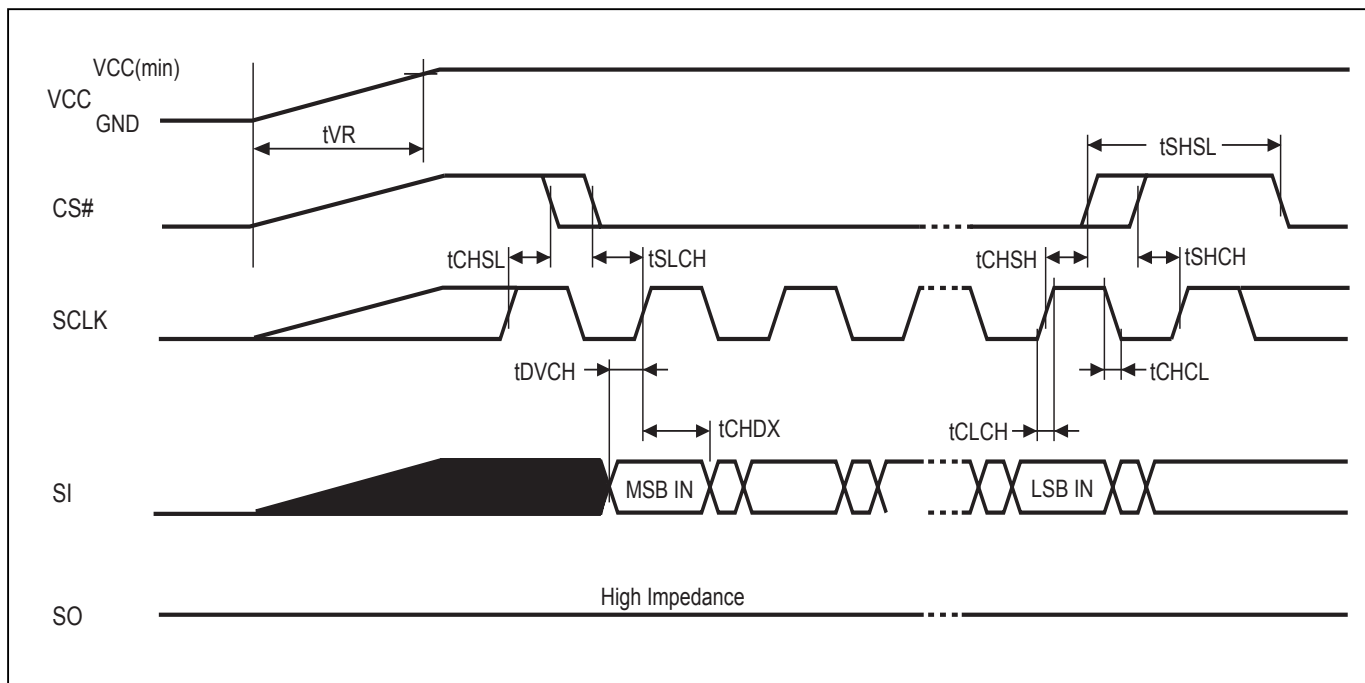
## OPERATING CONDITIONS

### At Device Power-Up and Power-Down

AC timing illustrated in Figure 28 and Figure 29 are the supply voltages and the control signals at device power-up and power-down. If the timing in the figures is ignored, the device will not operate correctly.

During power-up and power down, CS# needs to follow the voltage applied on VCC to keep the device not be selected. The CS# can be driven low when VCC reach Vcc(min.) and wait a period of tVSL.

**Figure 28. AC Timing at Device Power-Up**



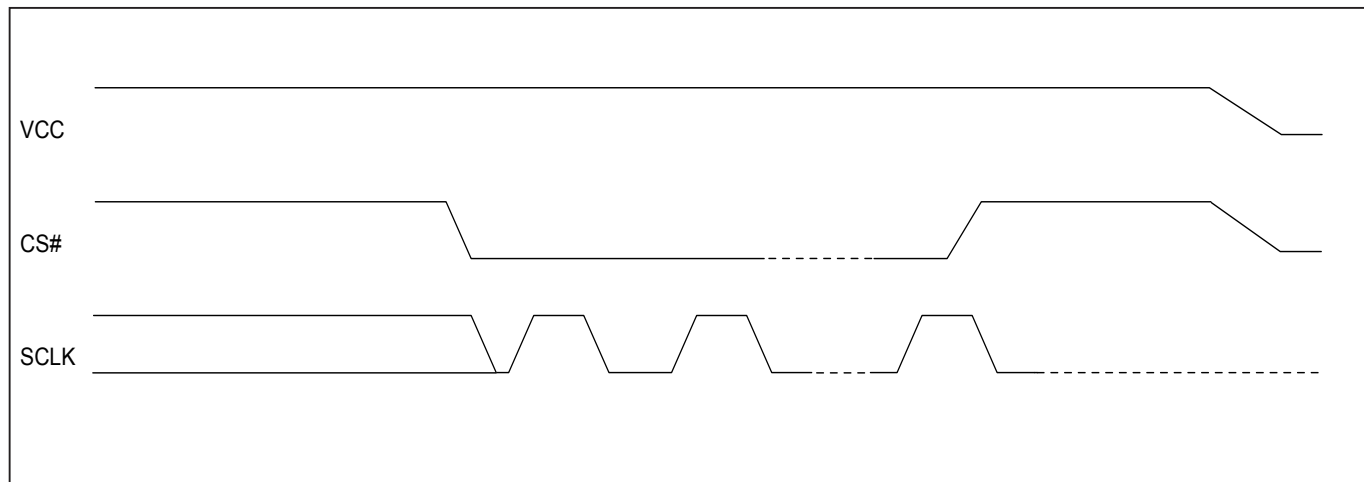
| Symbol | Parameter     | Notes | Min. | Max.   | Unit |
|--------|---------------|-------|------|--------|------|
| tVR    | VCC Rise Time | 1     | 0.5  | 500000 | us/V |

#### Notes :

1. Sampled, not 100% tested.
2. For AC spec tCHSL, tSLCH, tDVCH, tCHDX, tSHSL, tCHSH, tSHCH, tCHCL, tCLCH in the figure, please refer to "AC CHARACTERISTICS" table.

**Figure 29. Power-Down Sequence**

During power down, CS# needs to follow the voltage drop on VCC to avoid mis-operation.



**ERASE AND PROGRAMMING PERFORMANCE**

| Parameter                                    | Min.    | Typ. (1) | Max. (2) | Unit   |
|----------------------------------------------|---------|----------|----------|--------|
| Write Status Register Cycle Time             |         | 5        | 40       | ms     |
| Sector erase Time                            |         | 60       | 300      | ms     |
| Block erase Time                             |         | 0.7      | 2        | s      |
| Chip Erase Time                              |         | 3.5      | 7.5      | s      |
| Byte Program Time (via page program command) |         | 9        | 300      | us     |
| Page Program Time                            |         | 1.4      | 5        | ms     |
| Erase/Program Cycle                          | 100,000 |          |          | cycles |

**Note:**

1. Typical program and erase time assumes the following conditions: 25°C, 3.3V, and checker board pattern.
2. Under worst conditions of 85°C and 2.7V.
3. System-level overhead is the time required to execute the first-bus-cycle sequence for the programming command.

**DATA RETENTION**

| Parameter      | Condition | Min. | Max. | Unit  |
|----------------|-----------|------|------|-------|
| Data retention | 55°C      | 20   |      | years |

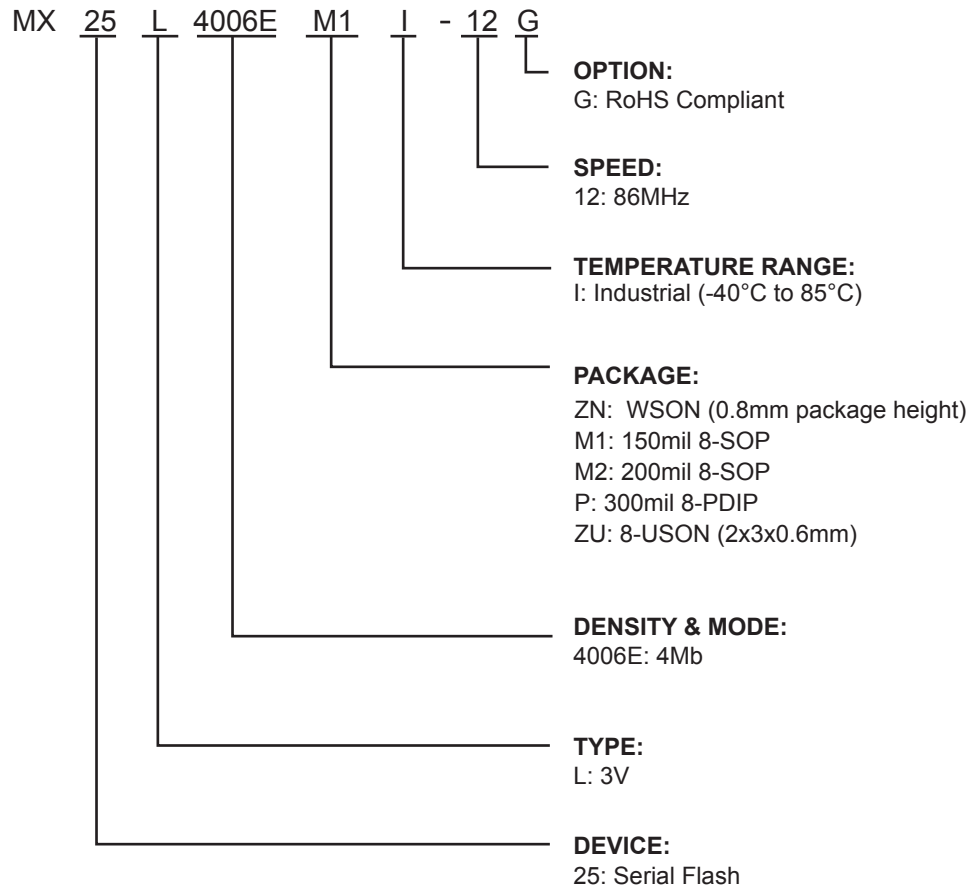
**LATCH-UP CHARACTERISTICS**

|                                                                               | Min.   | Max.       |
|-------------------------------------------------------------------------------|--------|------------|
| Input Voltage with respect to GND on all power pins, SI, CS#                  | -1.0V  | 2 VCCmax   |
| Input Voltage with respect to GND on SO                                       | -1.0V  | VCC + 1.0V |
| Current                                                                       | -100mA | +100mA     |
| Includes all pins except VCC. Test conditions: VCC = 3.0V, one pin at a time. |        |            |

**ORDERING INFORMATION**

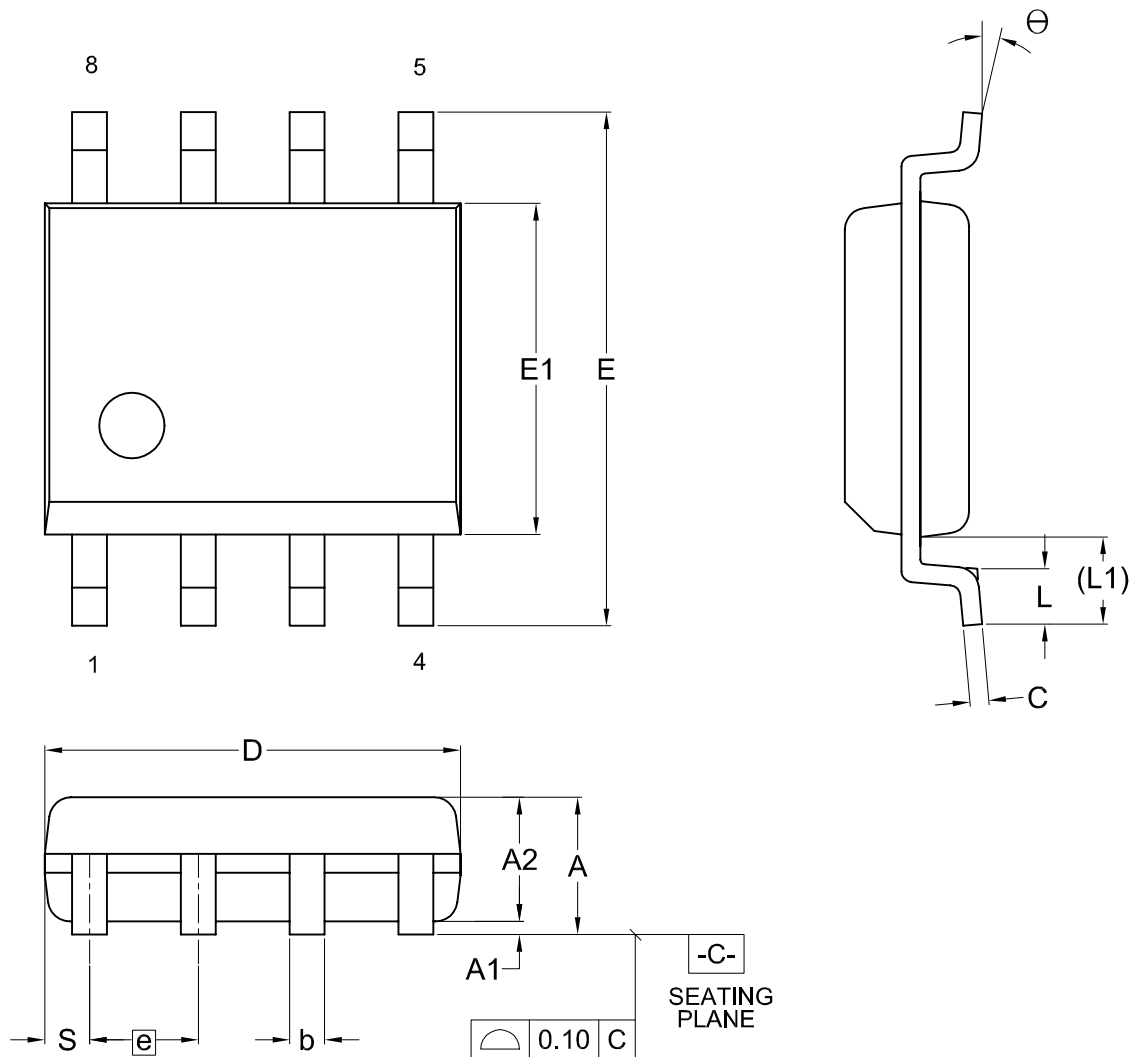
| PART NO.          | CLOCK<br>(MHz) | OPERATING<br>CURRENT(mA) | STANDBY<br>CURRENT(uA) | Temperature | PACKAGE                | Remark            |
|-------------------|----------------|--------------------------|------------------------|-------------|------------------------|-------------------|
| MX25L4006EM1I-12G | 86             | 12                       | 10                     | -40~85°C    | 8-SOP<br>(150mil)      | RoHS<br>Compliant |
| MX25L4006EM2I-12G | 86             | 12                       | 10                     | -40~85°C    | 8-SOP<br>(200mil)      | RoHS<br>Compliant |
| MX25L4006EPI-12G  | 86             | 12                       | 10                     | -40~85°C    | 8-PDIP<br>(300mil)     | RoHS<br>Compliant |
| MX25L4006EZNI-12G | 86             | 12                       | 10                     | -40~85°C    | 8-land WSON<br>(6x5mm) | RoHS<br>Compliant |
| MX25L4006EZUI-12G | 86             | 12                       | 10                     | -40~85°C    | 8-USON<br>(2x3x0.6mm)  | RoHS<br>Compliant |

## PART NAME DESCRIPTION



### PACKAGE INFORMATION

Doe. Title: Package Outline for SOP 8L (150MIL)

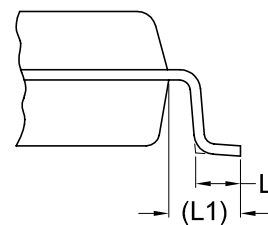
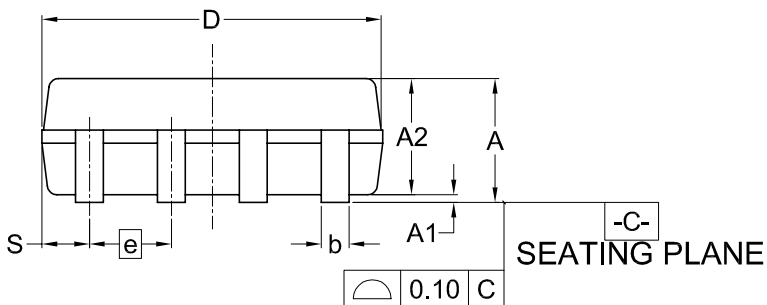
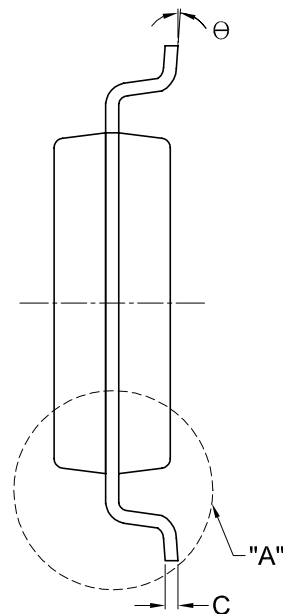
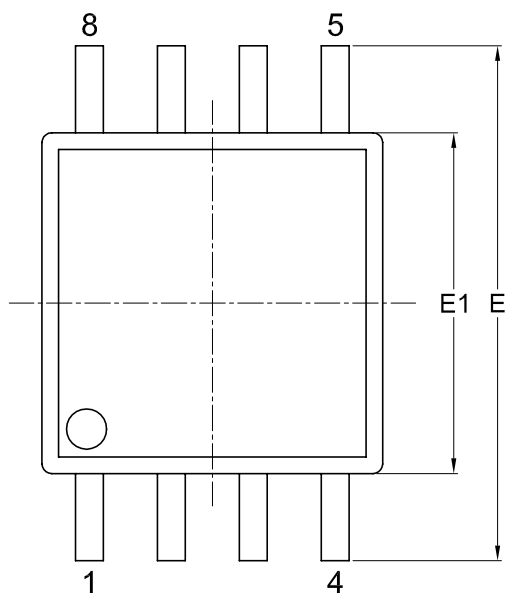


Dimensions (inch dimensions are derived from the original mm dimensions)

| SYMBOL |      | A     | A1    | A2    | b     | C     | D     | E     | E1    | e     | L     | L1    | S     | θ |
|--------|------|-------|-------|-------|-------|-------|-------|-------|-------|-------|-------|-------|-------|---|
| UNIT   |      |       |       |       |       |       |       |       |       |       |       |       |       |   |
| mm     | Min. | ---   | 0.10  | 1.35  | 0.36  | 0.15  | 4.77  | 5.80  | 3.80  |       | 0.46  | 0.85  | 0.41  | 0 |
|        | Nom. | ---   | 0.15  | 1.45  | 0.41  | 0.20  | 4.90  | 5.99  | 3.90  | 1.27  | 0.66  | 1.05  | 0.54  | 5 |
|        | Max. | 1.75  | 0.20  | 1.55  | 0.51  | 0.25  | 5.03  | 6.20  | 4.00  |       | 0.86  | 1.25  | 0.67  | 8 |
| Inch   | Min. | ---   | 0.004 | 0.053 | 0.014 | 0.006 | 0.188 | 0.228 | 0.150 |       | 0.018 | 0.033 | 0.016 | 0 |
|        | Nom. | ---   | 0.006 | 0.057 | 0.016 | 0.008 | 0.193 | 0.236 | 0.154 | 0.050 | 0.026 | 0.041 | 0.021 | 5 |
|        | Max. | 0.069 | 0.008 | 0.061 | 0.020 | 0.010 | 0.198 | 0.244 | 0.158 |       | 0.034 | 0.049 | 0.026 | 8 |

| Dwg. No.  | Revision | Reference |      |  |  |
|-----------|----------|-----------|------|--|--|
|           |          | JEDEC     | EIAJ |  |  |
| 6110-1401 | 7        | MS-012    |      |  |  |

Doc. Title: Package Outline for SOP 8L 200MIL (official name - 209MIL)



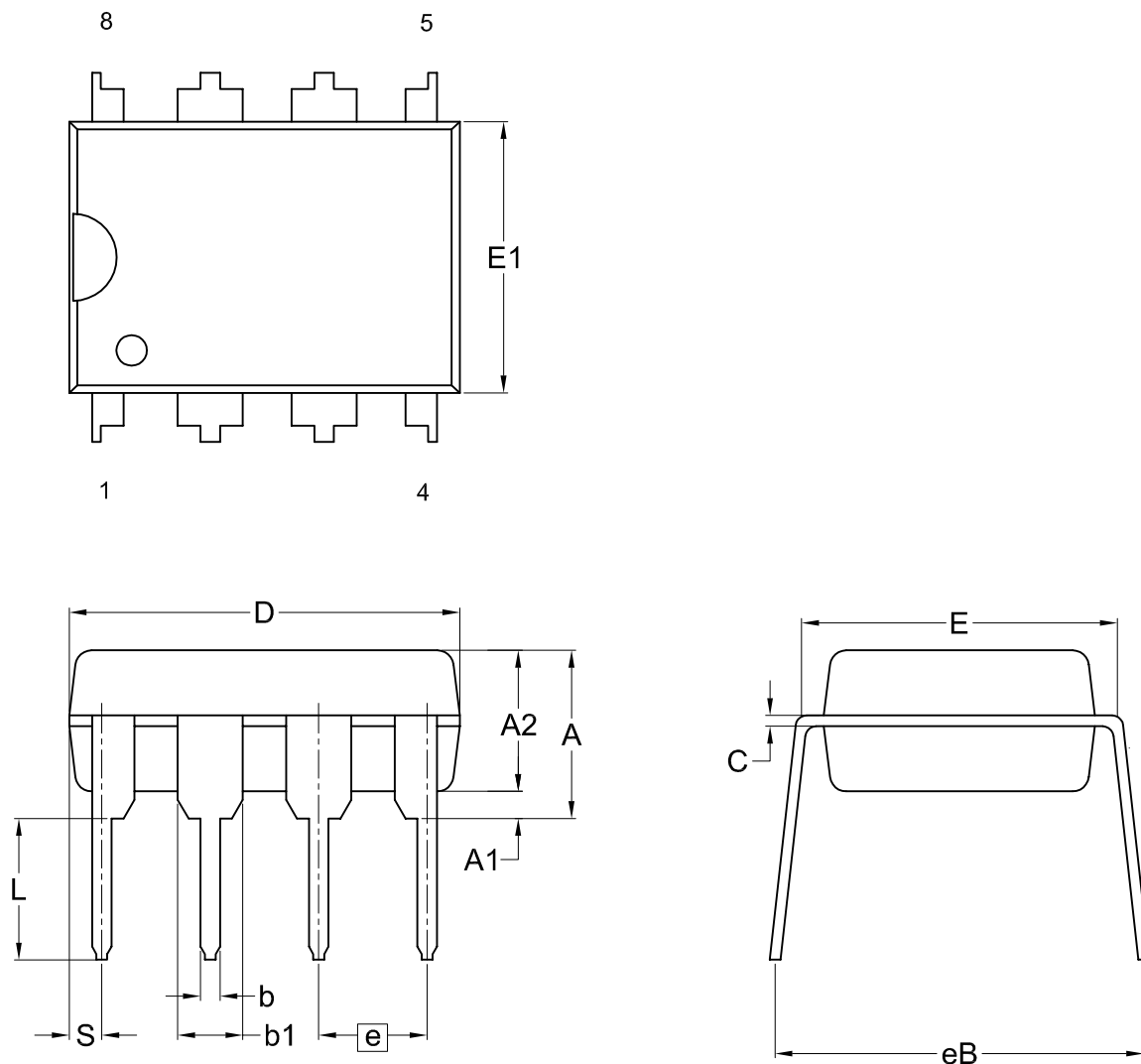
DETAIL "A"

Dimensions (inch dimensions are derived from the original mm dimensions)

| SYMBOL |      | A     | A1    | A2    | b     | C     | D     | E     | E1    | e     | L     | L1    | S     | $\theta$ |
|--------|------|-------|-------|-------|-------|-------|-------|-------|-------|-------|-------|-------|-------|----------|
| UNIT   |      |       |       |       |       |       |       |       |       |       |       |       |       |          |
| mm     | Min. | ---   | 0.05  | 1.70  | 0.36  | 0.19  | 5.13  | 7.70  | 5.18  | ---   | 0.50  | 1.21  | 0.62  | 0        |
|        | Nom. | ---   | 0.15  | 1.80  | 0.41  | 0.20  | 5.23  | 7.90  | 5.28  | 1.27  | 0.65  | 1.31  | 0.74  | 5        |
|        | Max. | 2.16  | 0.20  | 1.91  | 0.51  | 0.25  | 5.33  | 8.10  | 5.38  | ---   | 0.80  | 1.41  | 0.88  | 8        |
| Inch   | Min. | ---   | 0.002 | 0.067 | 0.014 | 0.007 | 0.202 | 0.303 | 0.204 | ---   | 0.020 | 0.048 | 0.024 | 0        |
|        | Nom. | ---   | 0.006 | 0.071 | 0.016 | 0.008 | 0.206 | 0.311 | 0.208 | 0.050 | 0.026 | 0.052 | 0.029 | 5        |
|        | Max. | 0.085 | 0.008 | 0.075 | 0.020 | 0.010 | 0.210 | 0.319 | 0.212 | ---   | 0.031 | 0.056 | 0.035 | 8        |

| Dwg. No.  | Revision | Reference |      |  |  |
|-----------|----------|-----------|------|--|--|
|           |          | JEDEC     | EIAJ |  |  |
| 6110-1406 | 3        |           |      |  |  |

Doc. Title: Package Outline for PDIP 8L (300MIL)



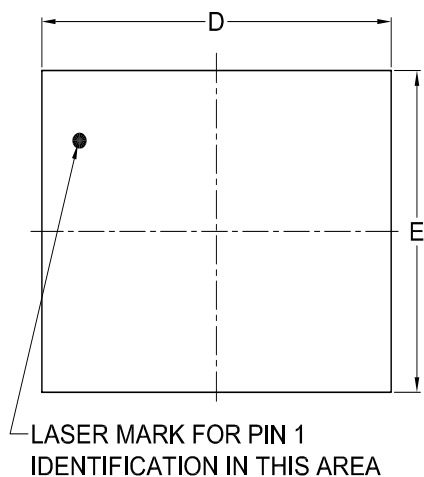
Dimensions (inch dimensions are derived from the original mm dimensions)

| SYMBOL |      | A     | A1    | A2    | b     | b1    | C     | D     | E     | E1    | e     | eB    | L     | S     |
|--------|------|-------|-------|-------|-------|-------|-------|-------|-------|-------|-------|-------|-------|-------|
| UNIT   |      |       |       |       |       |       |       |       |       |       |       |       |       |       |
| mm     | Min. | —     | 0.38  | 3.18  | 0.36  | 1.14  | 0.20  | 9.02  | 7.62  | 6.22  | —     | 7.87  | 2.92  | 0.76  |
|        | Nom. | —     | —     | 3.30  | 0.46  | 1.52  | 0.25  | 9.27  | 7.87  | 6.35  | 2.54  | 8.89  | 3.30  | 1.14  |
|        | Max. | 5.33  | —     | 3.43  | 0.56  | 1.78  | 0.36  | 10.16 | 8.13  | 6.48  | —     | 9.53  | 3.81  | 1.52  |
| Inch   | Min. | ---   | 0.015 | 0.125 | 0.014 | 0.045 | 0.008 | 0.355 | 0.300 | 0.245 | ---   | 0.310 | 0.115 | 0.030 |
|        | Nom. | ---   | —     | 0.130 | 0.018 | 0.060 | 0.010 | 0.365 | 0.310 | 0.250 | 0.100 | 0.350 | 0.130 | 0.045 |
|        | Max. | 0.210 | —     | 0.135 | 0.022 | 0.070 | 0.014 | 0.400 | 0.320 | 0.255 | ---   | 0.375 | 0.150 | 0.060 |

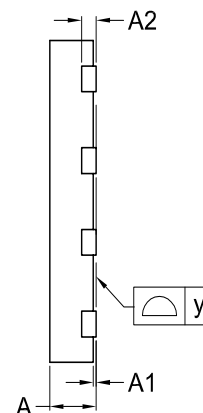
| Dwg. No.  | Revision | Reference |      |  |  |
|-----------|----------|-----------|------|--|--|
|           |          | JEDEC     | EIAJ |  |  |
| 6110-0201 | 7        | MS-001    |      |  |  |



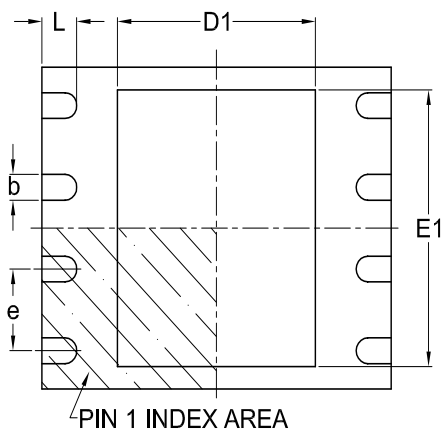
Doc. Title: Package Outline for WSON 8L (6x5x0.8MM, LEAD PITCH 1.27MM)



TOP VIEW



SIDE VIEW



BOTTOM VIEW

Dimensions (inch dimensions are derived from the original mm dimensions)

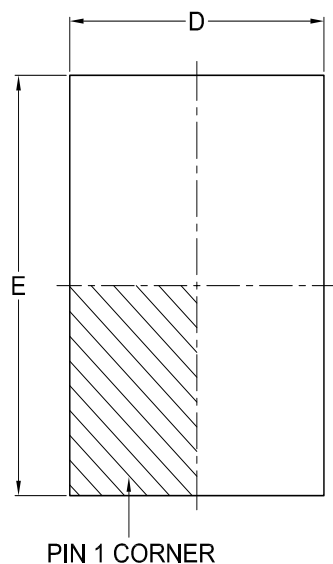
\*1 : This package has exposed metal pad underneath the package , it can't contact to metal trace or pad on board.

\*2 : The exposed pad size must not violate the min. metal separation requirement, 0.2mm with terminals.

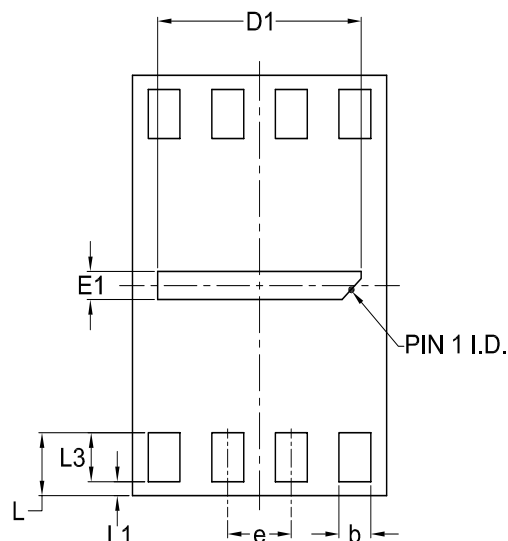
| SYMBOL |      | A     | A1    | A2    | b     | D     | D1    | E     | E1    | L     | e    | y     |
|--------|------|-------|-------|-------|-------|-------|-------|-------|-------|-------|------|-------|
| UNIT   |      |       |       |       |       |       |       |       |       |       |      |       |
| mm     | Min. | 0.70  | ---   | —     | 0.35  | 5.90  | 3.30  | 4.90  | 3.90  | 0.50  | —    | 0.00  |
|        | Nom. | ---   | ---   | 0.20  | 0.40  | 6.00  | 3.40  | 5.00  | 4.00  | 0.60  | 1.27 | ---   |
|        | Max. | 0.80  | 0.05  | —     | 0.48  | 6.10  | 3.50  | 5.10  | 4.10  | 0.75  | —    | 0.08  |
| Inch   | Min. | 0.028 | ---   | —     | 0.014 | 0.232 | 0.129 | 0.193 | 0.154 | 0.020 | —    | 0.00  |
|        | Nom. | ---   | ---   | 0.008 | 0.016 | 0.236 | 0.134 | 0.197 | 0.157 | 0.024 | 0.05 | —     |
|        | Max. | 0.032 | 0.002 | —     | 0.019 | 0.240 | 0.138 | 0.201 | 0.161 | 0.030 | —    | 0.003 |

| Dwg. No.  | Revision | Reference |      |  |  |
|-----------|----------|-----------|------|--|--|
|           |          | JEDEC     | EIAJ |  |  |
| 6110-3401 | 5        | MO-220    |      |  |  |

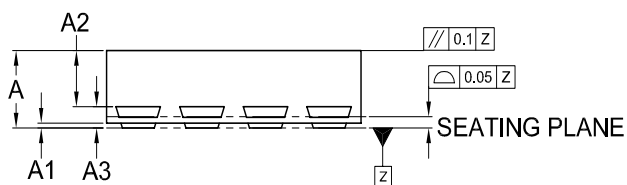
Doc. Title: Package Outline for USON 8L (2x3x0.6MM, LEAD PITCH 0.5MM)



TOP VIEW



BOTTOM VIEW



SIDE VIEW

Dimensions (inch dimensions are derived from the original mm dimensions)

\*1: This package has exposed metal pad underneath the package , it can't contact to metal trace or pad on board.

\*2: The exposed pad size must not violate the min. metal separation requirement, 0.2mm with terminals.

| SYMBOL |      | A     | A1     | A2     | A3     | b     | D     | D1    | E     | E1    | e     | L     | L1    | L3    |
|--------|------|-------|--------|--------|--------|-------|-------|-------|-------|-------|-------|-------|-------|-------|
| UNIT   |      |       |        |        |        |       |       |       |       |       |       |       |       |       |
| mm     | Min. | 0.50  | 0      | ---    | ---    | 0.20  | 1.90  | 1.50  | 2.90  | 0.10  | ---   | 0.40  | ---   | 0.30  |
|        | Nom. | 0.55  | 0.035  | 0.40   | 0.152  | 0.25  | 2.00  | 1.60  | 3.00  | 0.20  | 0.50  | 0.45  | ---   | ---   |
|        | Max. | 0.60  | 0.05   | 0.425  | ---    | 0.30  | 2.10  | 1.70  | 3.10  | 0.30  | ---   | 0.50  | 0.15  | ---   |
| Inch   | Min. | 0.020 | 0      | ---    | ---    | 0.008 | 0.075 | 0.059 | 0.114 | 0.004 | ---   | 0.016 | ---   | 0.012 |
|        | Nom. | 0.022 | 0.0014 | 0.016  | 0.0060 | 0.010 | 0.079 | 0.063 | 0.118 | 0.008 | 0.020 | 0.018 | ---   | ---   |
|        | Max. | 0.024 | 0.002  | 0.0167 | ---    | 0.012 | 0.083 | 0.067 | 0.122 | 0.012 | ---   | 0.020 | 0.006 | ---   |

| Dwg. No.  | Revision | Reference |      |  |  |
|-----------|----------|-----------|------|--|--|
|           |          | JEDEC     | EIAJ |  |  |
| 6110-3602 | 3        | MO-252    |      |  |  |

**REVISION HISTORY**

| <b>Revision No.</b> | <b>Description</b>                                            | <b>Page</b>           | <b>Date</b> |
|---------------------|---------------------------------------------------------------|-----------------------|-------------|
| 0.01                | 1. Modified "Initial Delivery State" description              | P27                   | MAY/19/2010 |
|                     | 2. Modified OTP Capable data from 1 to 0                      | P21                   |             |
|                     | 3. Revised Vcc Supply Minimum Voltage Address Bits            | P21                   |             |
|                     | 4. Changed wording from DMC to SFDP                           | P4,8,11,19            |             |
|                     | 5. Changed title from "Advanced Information" to "Preliminary" | P4                    |             |
|                     | 6. Corrected Max. Write Status Register Cycle Time            | P40                   |             |
|                     | 7. Revised SFDP sequence description                          | P19                   |             |
| 1.0                 | 1. Removed Preliminary                                        | P4                    | JUL/02/2010 |
|                     | 2. Removed SFDP sequence description & content table          | P4,8,11,19            |             |
|                     | 3. Removed Write Status Register Cycle Time in notes          | P23,37                |             |
| 1.1                 | 1. Added CS# rising and falling time description              | P8,23                 | OCT/26/2010 |
|                     | 2. Modified tW from 10(typ.)/100(max.) to 5(typ.)/40(max.)    | P23,37                |             |
|                     | 3. Added tSE(max.): 300ms                                     | P23,37                |             |
|                     | 4. Revised clock time to 86MHz                                | P38,39                |             |
|                     | 5. Removed note 2                                             | P13                   |             |
| 1.2                 | 1. Modified tVSL from 10us(min.) to 200us(min.)               | P24                   | MAR/21/2011 |
|                     | 2. Modified description for RoHS compliance                   | P4,38,39              |             |
|                     | 3. Added 8-USON package                                       | P4,5,38,39,44         |             |
| 1.3                 | 1. Added Read SFDP (RDSFDP) Mode                              | P4,8,11,<br>P19~24,29 | FEB/10/2012 |

Except for customized products which has been expressly identified in the applicable agreement, Macronix's products are designed, developed, and/or manufactured for ordinary business, industrial, personal, and/or household applications only, and not for use in any applications which may, directly or indirectly, cause death, personal injury, or severe property damages. In the event Macronix products are used in contradicted to their target usage above, the buyer shall take any and all actions to ensure said Macronix's product qualified for its actual use in accordance with the applicable laws and regulations; and Macronix as well as it's suppliers and/or distributors shall be released from any and all liability arisen therefrom.

Copyright© Macronix International Co., Ltd. 2010~2012. All rights reserved, including the trademarks and tradename thereof, such as Macronix, MXIC, MXIC Logo, MX Logo, Integrated Solutions Provider, NBit, Nbit, NBiit, Macronix NBit, eLiteFlash, XtraROM, Phines, KH Logo, BE-SONOS, KSMC, Kingtech, MXSMIO, Macronix vEE, Macronix MAP, Rich Audio, Rich Book, Rich TV, and FitCAM. The names and brands of other companies are for identification purposes only and may be claimed as the property of the respective companies.

For the contact and order information, please visit Macronix's Web site at: <http://www.macronix.com>